



*University of Hawai'i at Mānoa*

# ***Semiconductor detector R&D for future experiments in particle physics***

*Tracking, timing and particle identification*

Jennifer Ott

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Siegen, January 8, 2026



COLLEGE OF ENGINEERING  
UNIVERSITY of HAWAII at MĀNOA

# Introduction

Jennifer Ott

B.Sc., University of Helsinki, chemistry (2014)

M.Sc. University of Helsinki, radiochemistry (2015)

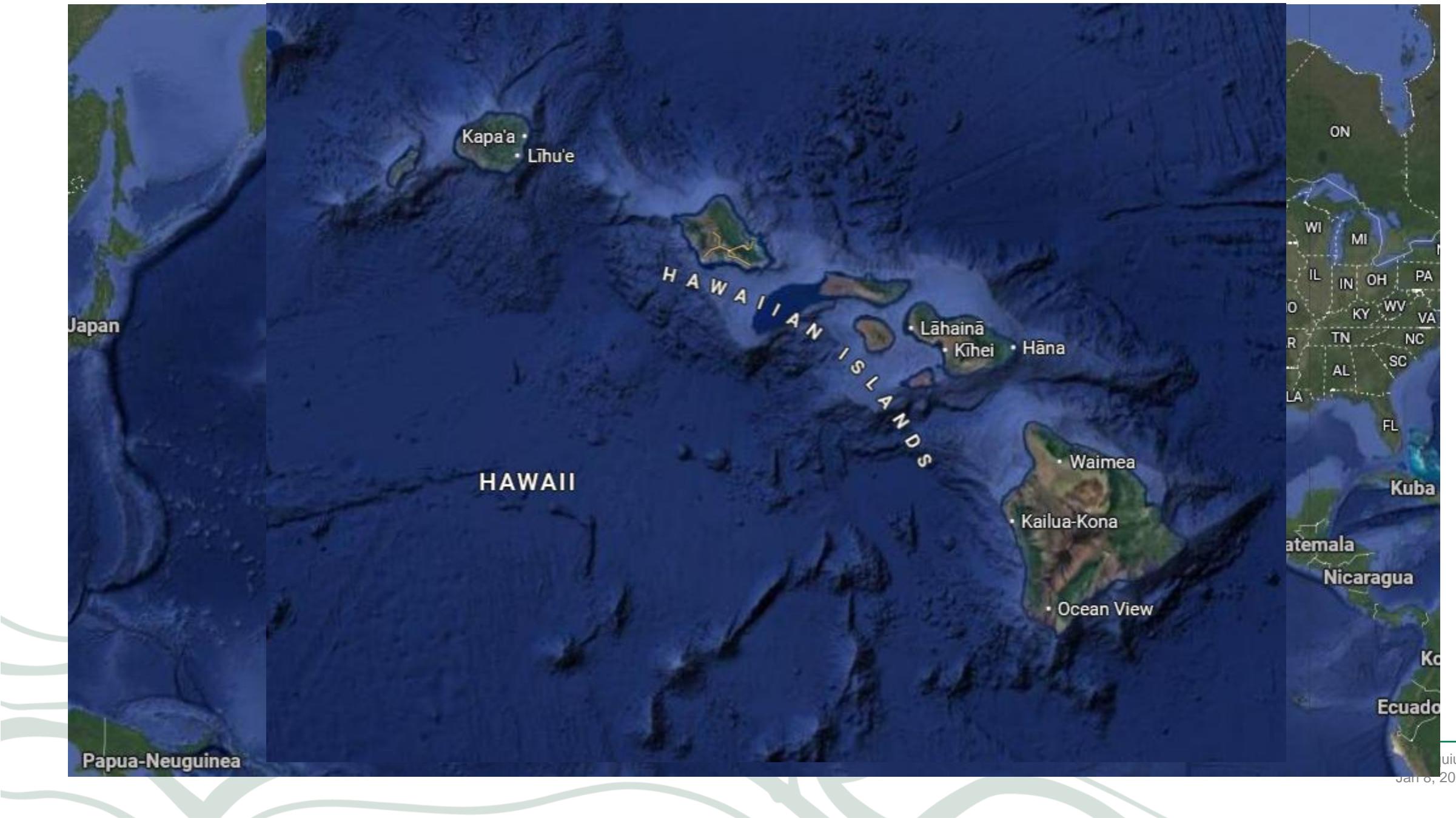
D. Sc. (Tech.) Helsinki Institute of Physics & Aalto University  
(spring 2021)

Postdoctoral researcher, UC Santa Cruz (2021-2024)

*Assistant professor in Electrical & Computer Engineering,  
cooperating graduate faculty in Physics & Astronomy,  
University of Hawai'i at Mānoa (2025 - )*



J. Ott, Siegen colloquium  
Jan 8, 2026







Jan 8, 2026



J. Ott, Siegen colloquium

# Background: UH

**The University of Hawai'i system encompasses several public university and community college campuses on the Hawaiian islands**

- Flagship campus in the **Mānoa** valley: the only R-1 ranked university in the state of Hawai'i
  - Among the most diverse student populations in the US; Minority-Serving Institution
  - Passed 20,000 enrolled students for the first time in AY24/25!



# Background: UH

UH is situated on the traditional and ancestral homelands of the Native Hawaiians - kānaka 'ōiwi

***Some Hawaiian words you may know, or encounter:***

***Aloha***

***Mahalo:*** thank you

***Kōkua:*** collaborate, support

***Makai:*** towards the ocean

***Mauka:*** inland-facing

# HEP detector R&D

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# Motivation: high-energy physics experiments

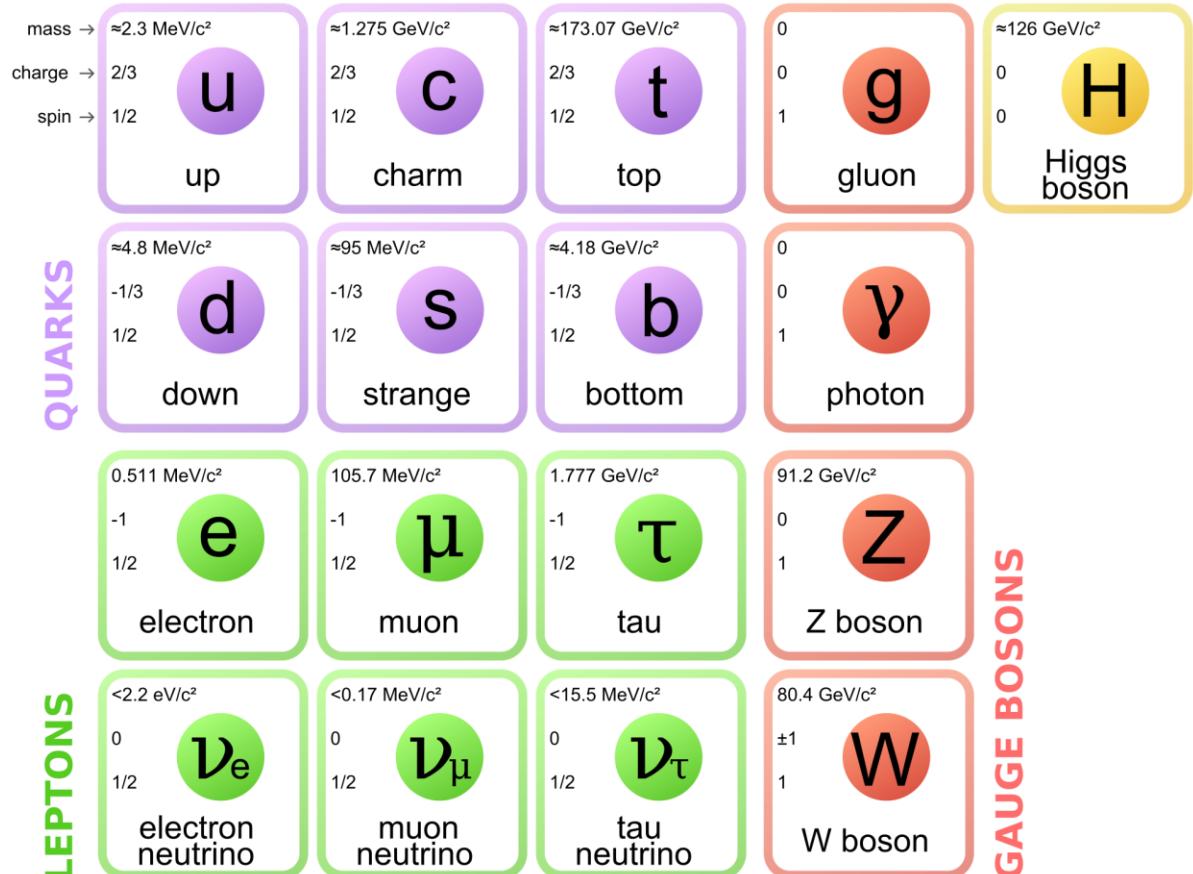
## The Standard Model of particle physics

- Describes properties and interactions of fundamental particles
- **Experimental discovery of the Higgs boson at the Large Hadron Collider in 2012 confirmed one of the most significant missing pieces!**

## Unsolved questions:

- Gravity (quantum mechanics & gravity)?
- Matter-antimatter imbalance?
- Dark matter, dark energy?

*Extremely small particles at very high energies*



# Astroparticle physics?

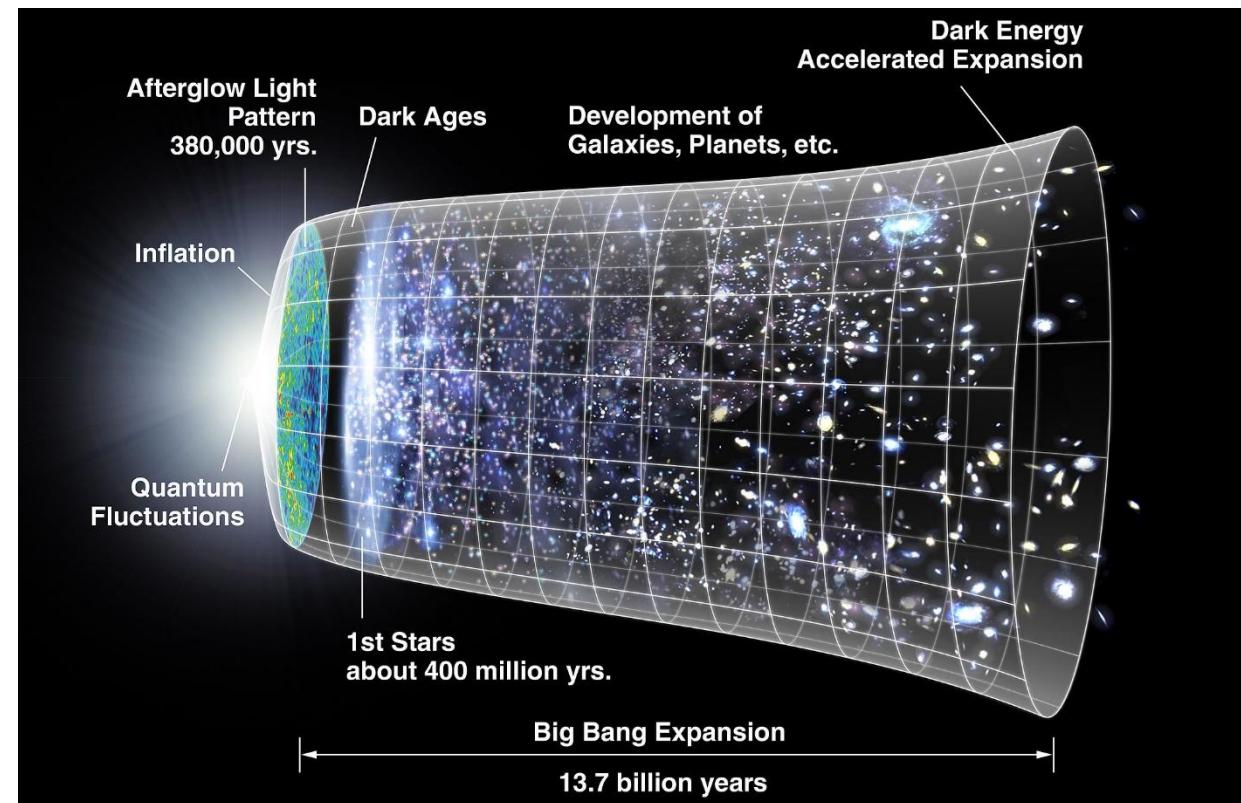
Extraterrestrial sources produce high-energy species!

- Cosmic particles: protons, muons
- Gamma rays

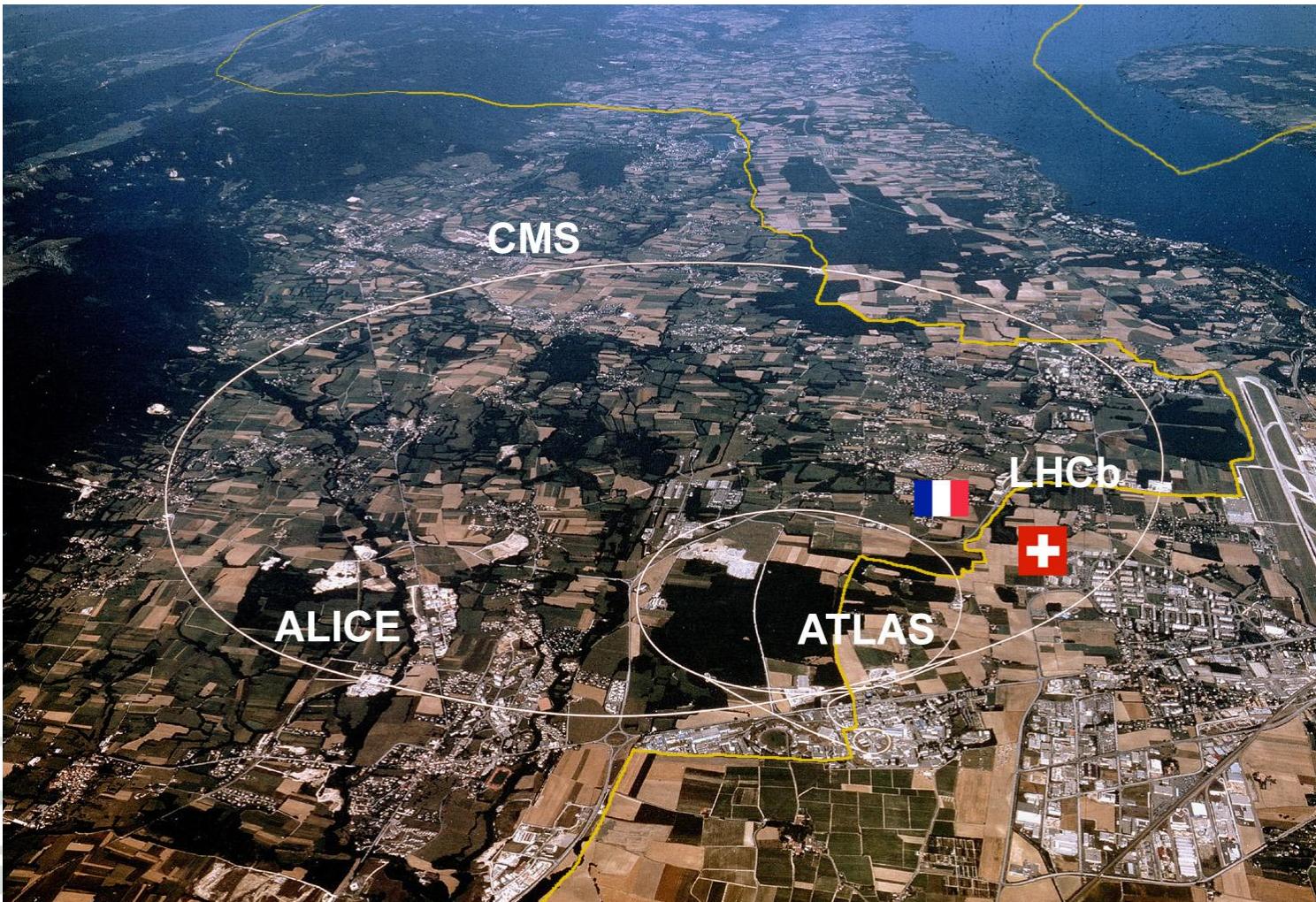
Provide information about processes in stars, galaxies, active galactic nuclei and objects with extreme mass (black holes, neutron stars)

- Formation of the universe
- Dark sectors
- Matter in extreme conditions

*For studying fundamental properties and interactions, e.g. of the standard model: too little statistics, impossible to build precision detectors in a specific location*



# The Large Hadron Collider



Circumference: 27 km

Primarily proton-proton (p-p) collisions:  
center-of-mass energy 13 TeV

Luminosity:  $2 \times 10^{34} \text{ cm}^{-2}\text{s}^{-1}$

Collision frequency: 40 MHz = **25 ns**

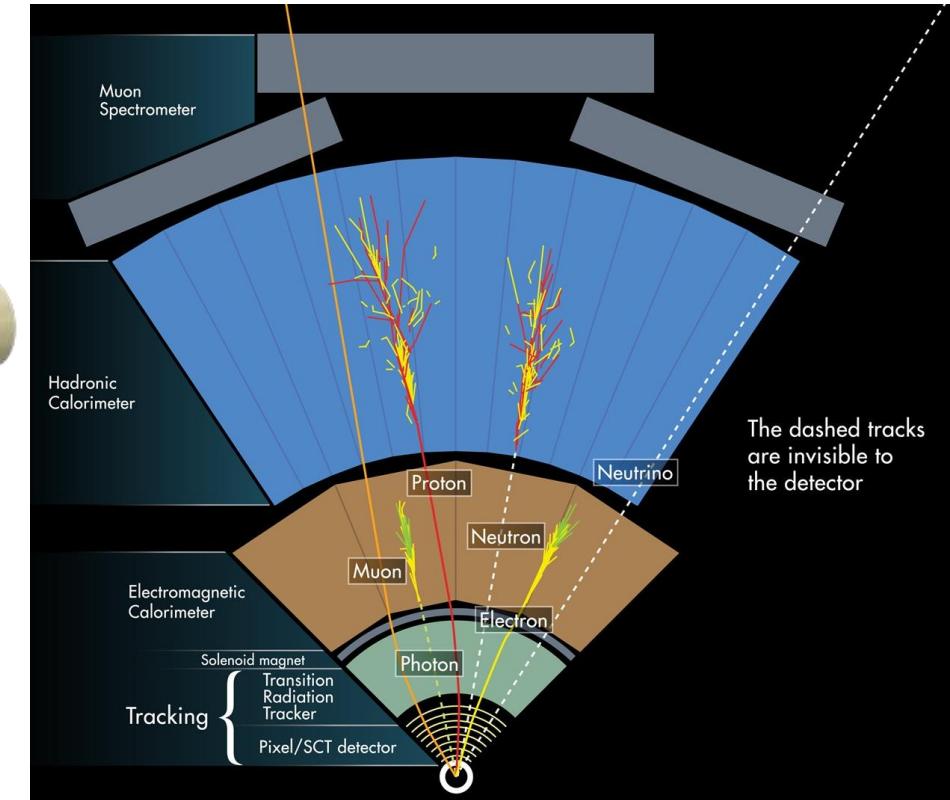
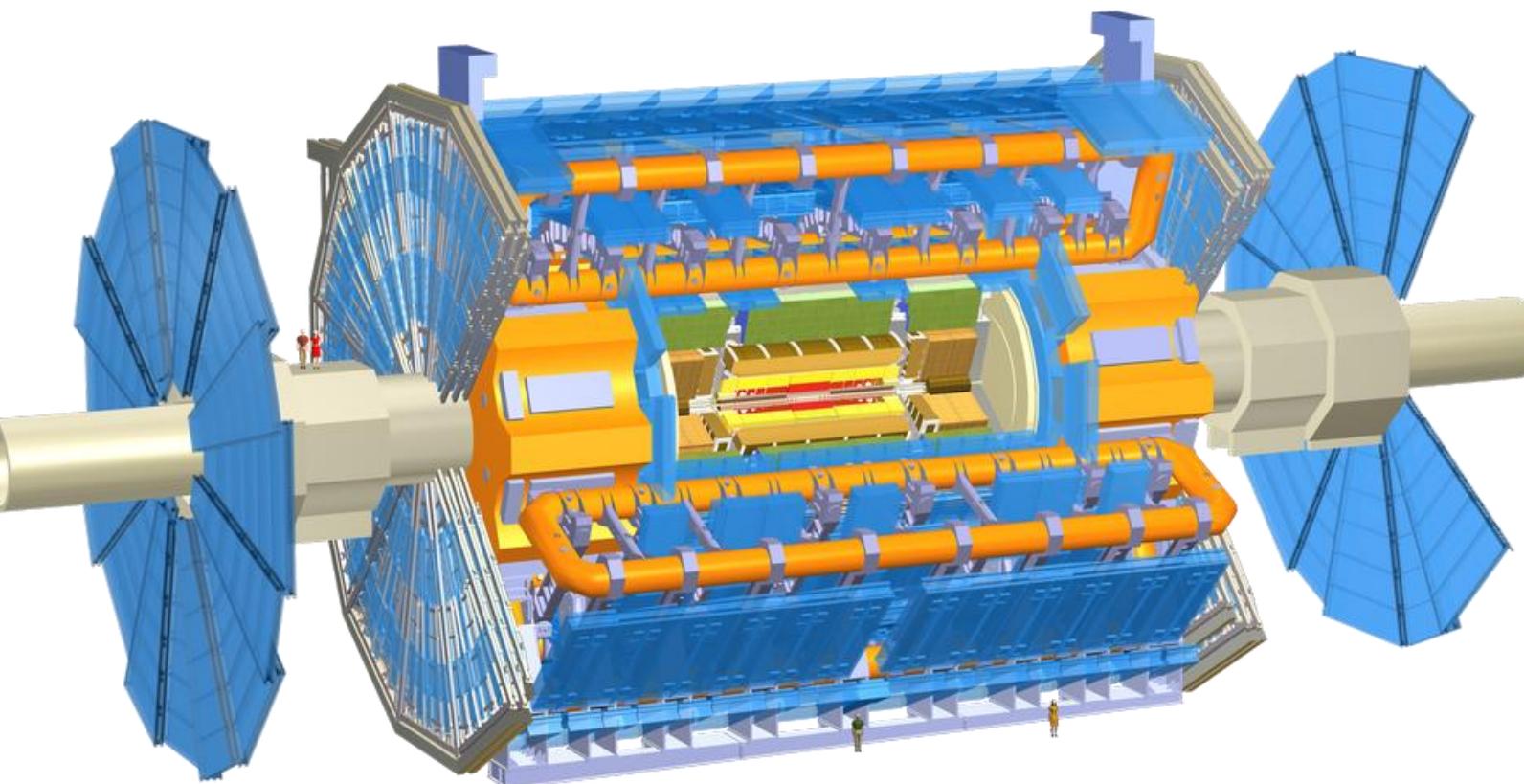


# Experimental particle physics

**Energies are very high compared to a normal laboratory scale**

- High energies require large amounts of absorber material → large detectors
- Some particle species interact so little that they cannot feasibly be stopped (or do not interact at all)

# Example: the ATLAS detector



**Multiple layers of specialized detector technology: tracking, calorimetry, spectrometers**

# Experimental particle physics

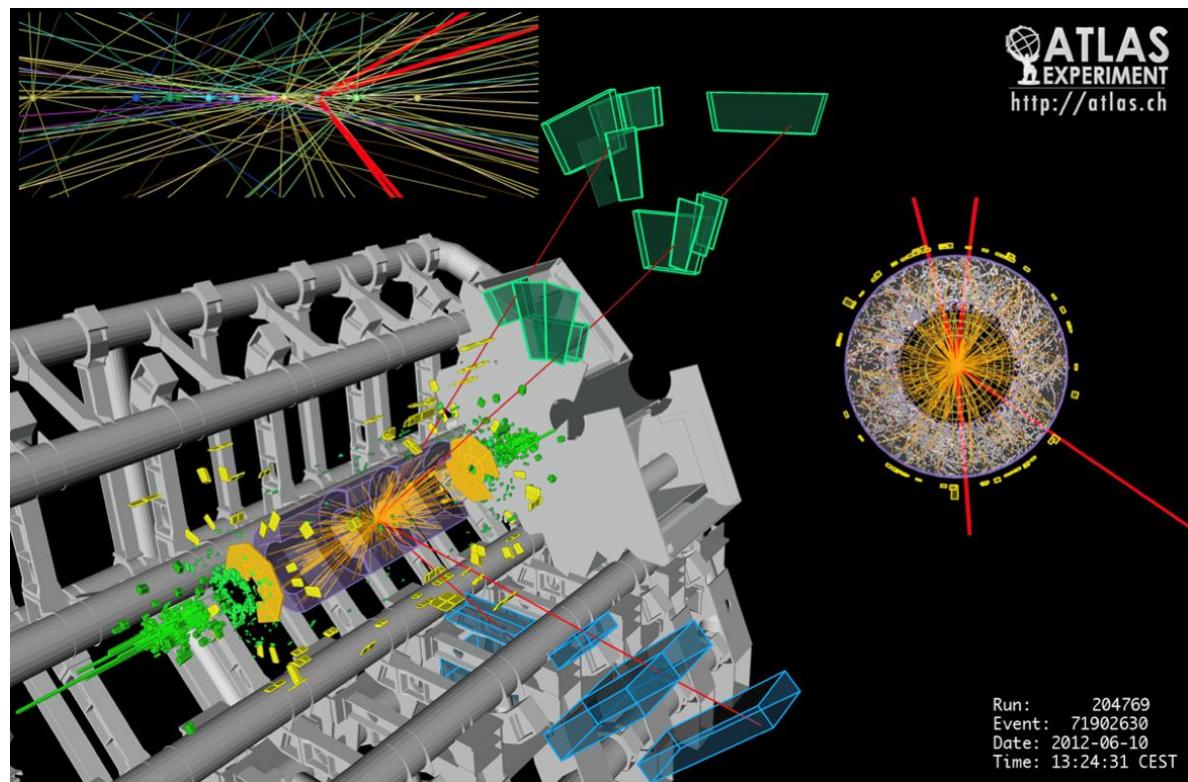
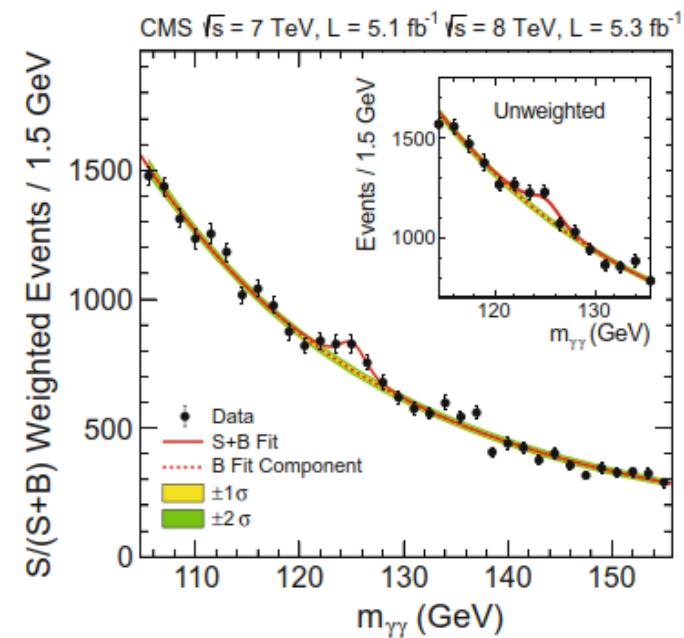
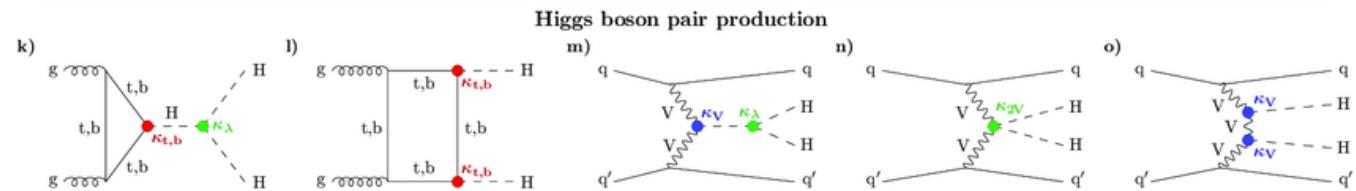
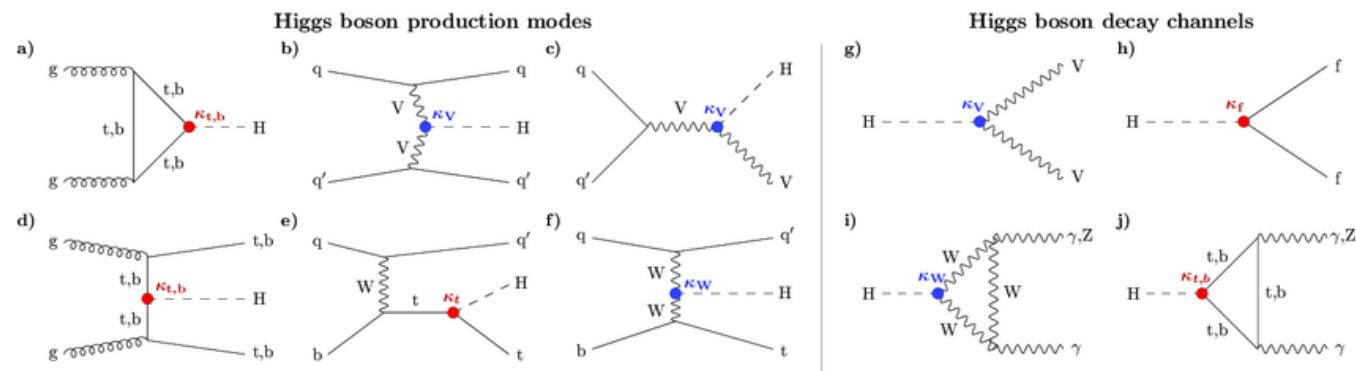
**Energies are very high compared to a normal laboratory scale**

- High energies require large amounts of absorber material → large detectors
- Some particle species interact so little that they cannot feasibly be stopped (or do not interact at all)

**Identification of unstable fundamental particles produced in the collisions relies on precision measurements of their decay products:**

- Energy
- Momentum
- Particle ID

*Conservational laws!*

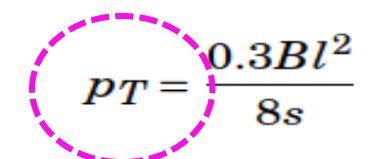


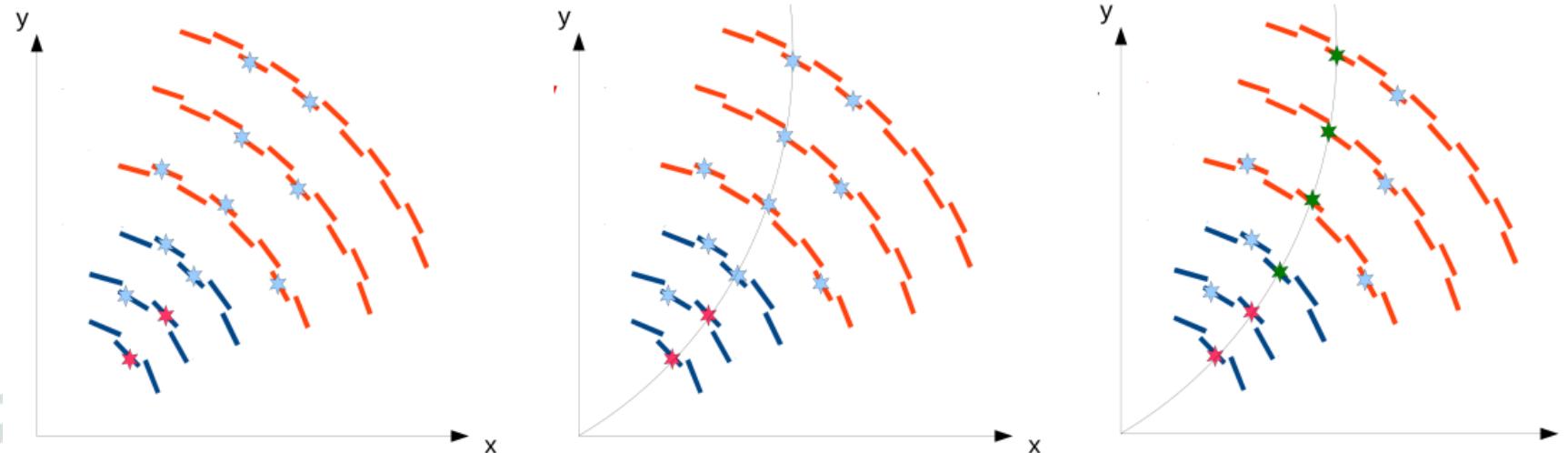
# Tracking detectors

Objective: determine the 'path' of a particle → calculate its momentum

In a magnetic field, charged particles are deflected:

$$\mathbf{F}_L = \frac{d\mathbf{p}}{dt} = q\mathbf{v} \times \mathbf{B}$$


$$p_T = \frac{0.3Bl^2}{8s}$$

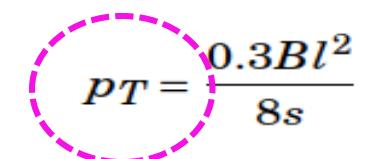


# Tracking detectors

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$$\mathbf{F}_L = \frac{d\mathbf{p}}{dt} = q\mathbf{v} \times \mathbf{B}$$


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**Requirements:**

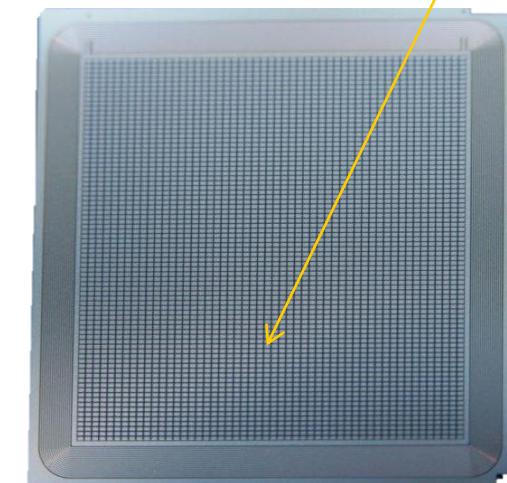
- Multiple layers
- Thin sensors
- Light material
- Capable of detecting small signal
- High spatial resolution = fine segmentation

*Avoid scattering of particles*

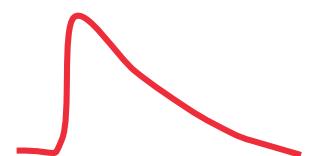
# “Solid-state detectors”

Direct interaction = detection of primary particle or photon, conversion to electric charge in a solid material

- ~~Polymers (bubble chambers etc)~~ *Structural change instead of charge*
- ~~Metals~~ *Conductive*
- ~~Gas detectors~~ *Electron-ion pairs, but not solid*
- ~~Scintillators + photodetectors~~ *Semiconductor detector is detecting secondary light*



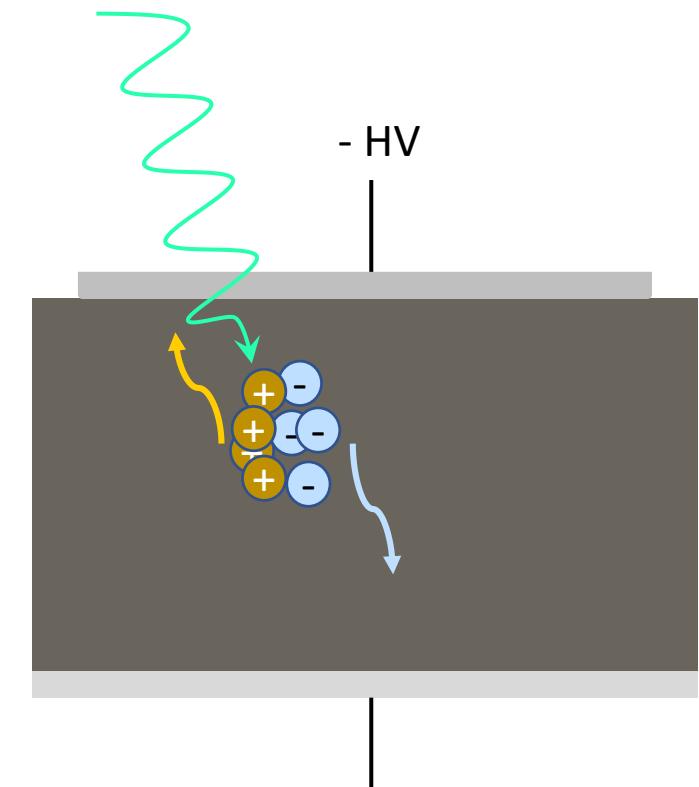
- **Semiconducting material: most commonly, but not exclusively, silicon**



# Semiconductor sensors

**Similar underlying operation principle as solar cell (more distantly related...) or a silicon photodiode**

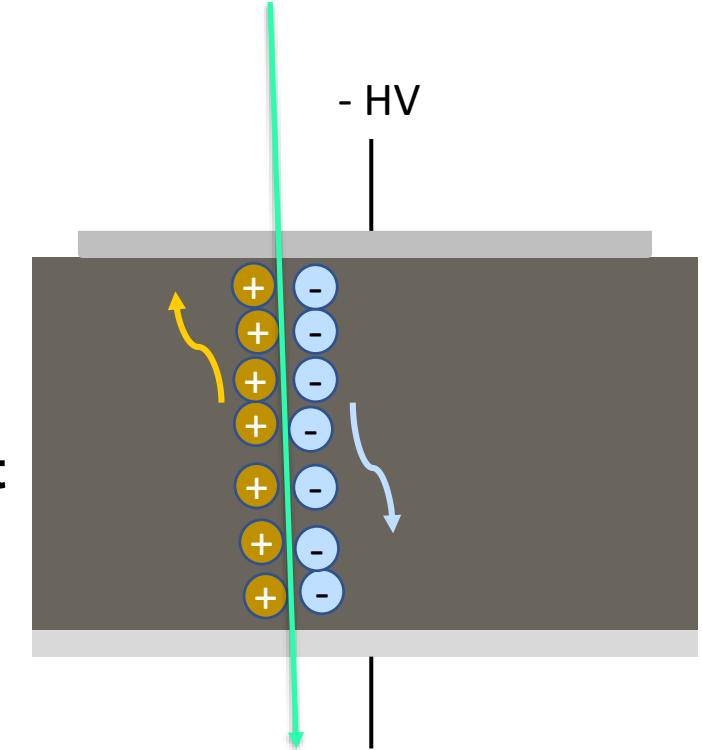
- Incident photon or particle generates electron-hole pairs
    - Depending on the band gap and work function of the semiconductor: e.g. 1.12 eV for Silicon
  - In an externally applied electric field, i.e. bias voltage, these charges are separated and drift to opposite electrodes
- **Signal is a current transient**



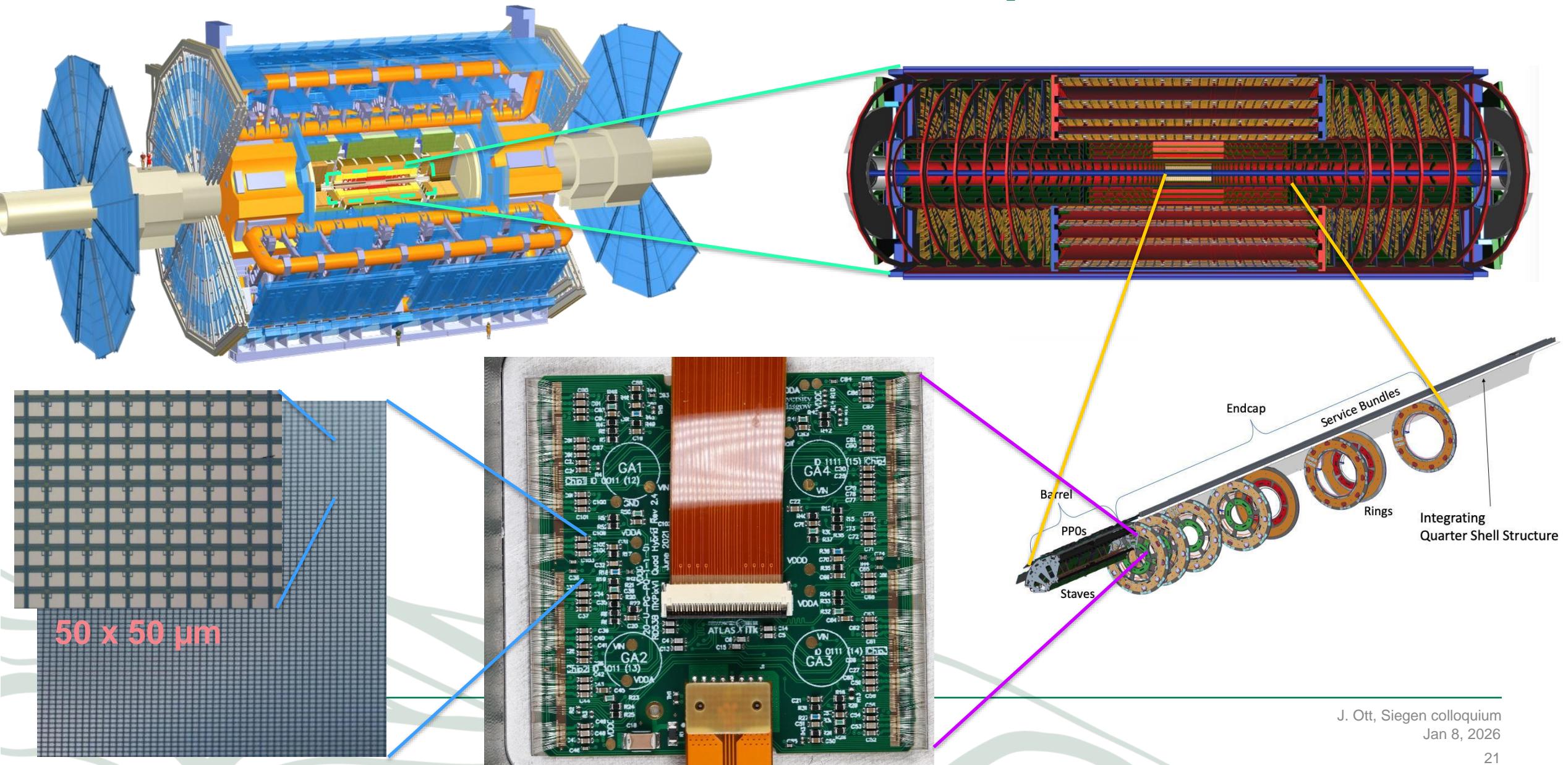
# Semiconductor sensors

*In most collider physics experiments, energies are above the scale of GeV, or at least many tens-hundreds of MeV*

- **Photons do not give a signal in the tracking detector**
  - ... As they are electrically neutral (and massless), the purpose of the tracking detector is lost in any case
- **Neutral particles do not interact electromagnetically, do not ionize the material**
- **Semiconductor sensor layers will not absorb, stop the particles!**
  - Instead of a single interaction, charge is generated along the trajectory of the particle in the sensor

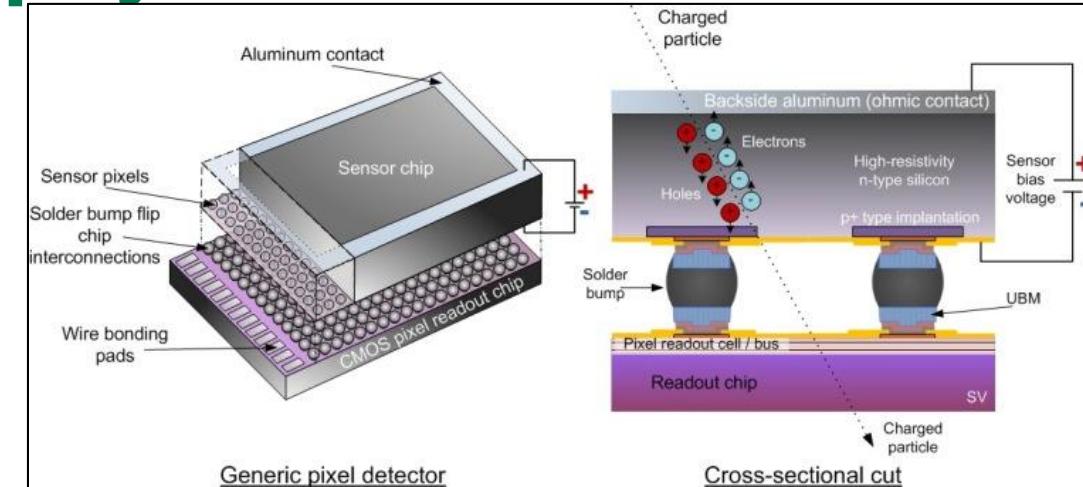


# ATLAS Inner Tracker pixels



# Pixel detectors in high-energy physics

- Research & development of sensors
- Research & development of readout electronics
  - Spatial resolution: decreasing pixel size
  - Radiation hardness
  - Scaling: size and surface area, power consumption
- Building tracking detectors for new collider experiments: sensor and front-end design, integration, services, cooling, quality control, ...
- **Integration of active sensor and readout circuitry: bump-bonding is reaching the limits of technical feasibility**
- **Other materials than silicon?**



<http://x-ray.camera/technology/flip-chip-bonding/>

# Example: the RD53 readout ASICs

New detectors are installed for the high-luminosity stage of the LHC, which is scheduled to start in 2029

## Pixel detectors:

- Radiation hardness
- Larger ASIC:  $\sim 2 \times 2$  cm
- Low occupancy,  $< 1\%$
- Smaller pixel size:  $25 \times 100$  or  $50 \times 50$   $\mu\text{m}$

ATLAS and CMS Experiments collaborated in developing a framework for the pixel readout chip through the 'RD53' collaboration

- 65 nm CMOS process at TSMC
- RD53A: divided into three regions with different front-end (linear, differential, synchronous)

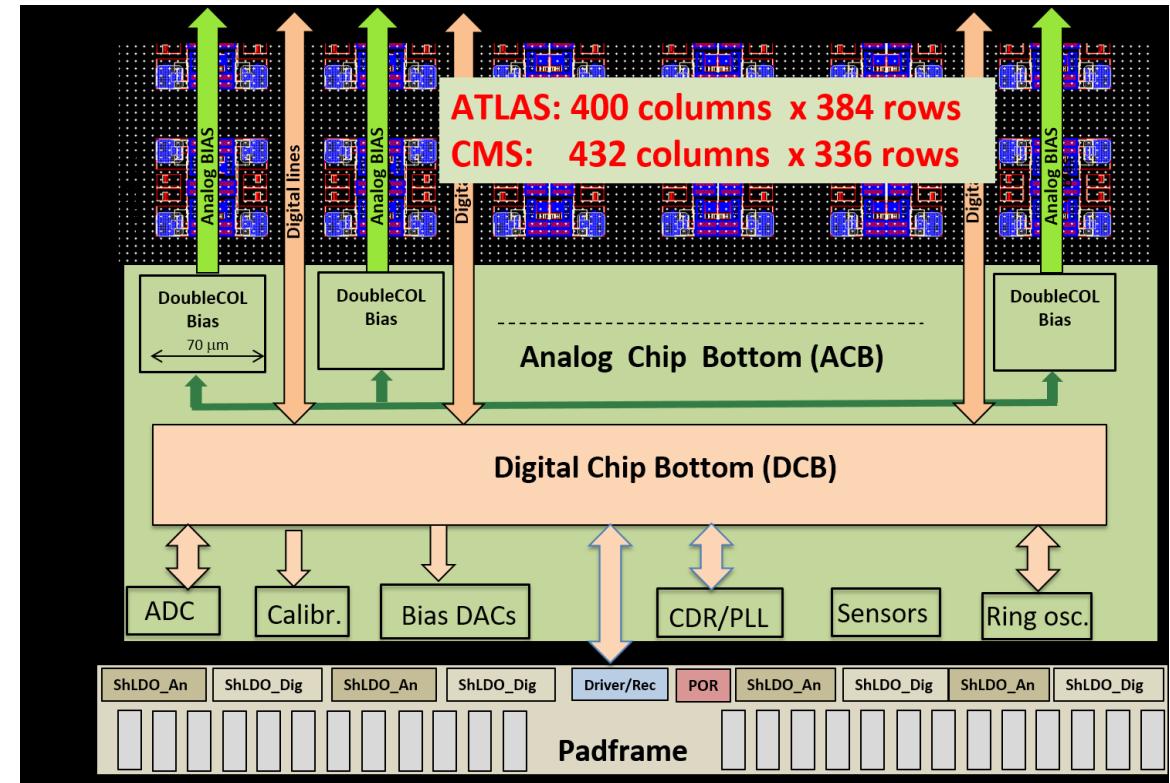
# RD53C – ITkpix v2

## RD53B: diverging into ITkpix (differential FE, for ATLAS) and CROC (linear FE, for CMS)

- Full chip size: 400 x 384 pixels in the case of ITkpix
  - Two tapeouts to finalize design and correct flaws, including critical ones in the ToT block

# RD53C: ITkpix v2 – final chip

- Full ToT functionality
  - Self-triggering

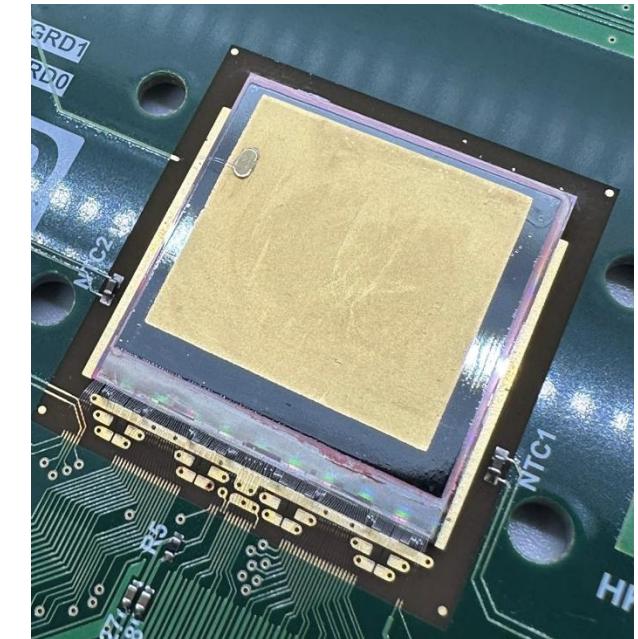
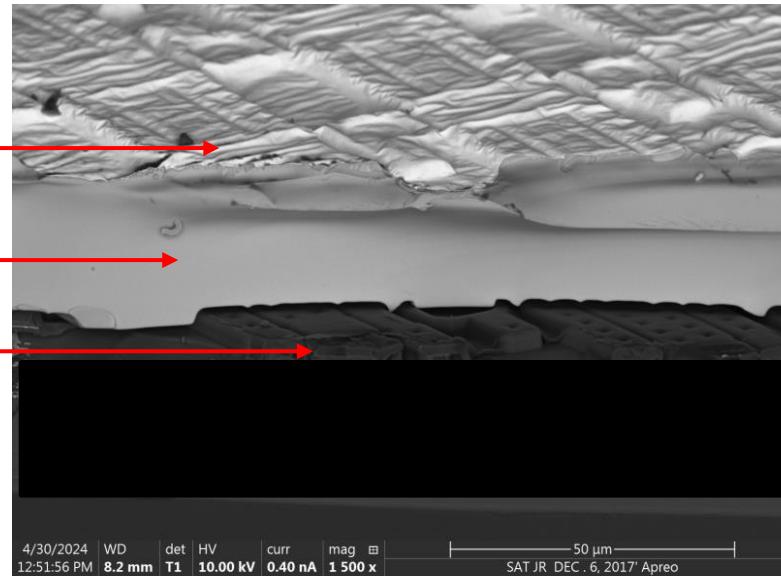
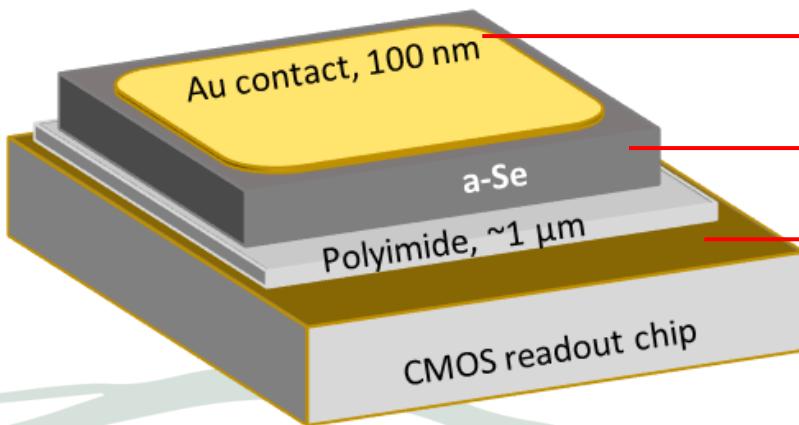


*M. Garcia-Sciveres et al (2024), RD53C manual, CERN-RD53-PUB-24-001*

# Research example: thin film detectors

Active sensor material is deposited directly onto the fully fabricated ASIC

- Here: amorphous Selenium
- No solder bumps or flip-chip assembly
- No separate sensor processing



*SEM cross-section of an a-Se / CMOS sensor, here with 25 μm a-Se*

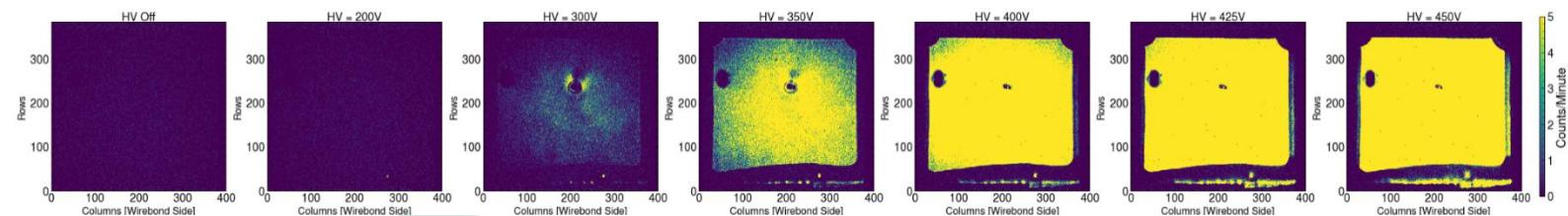
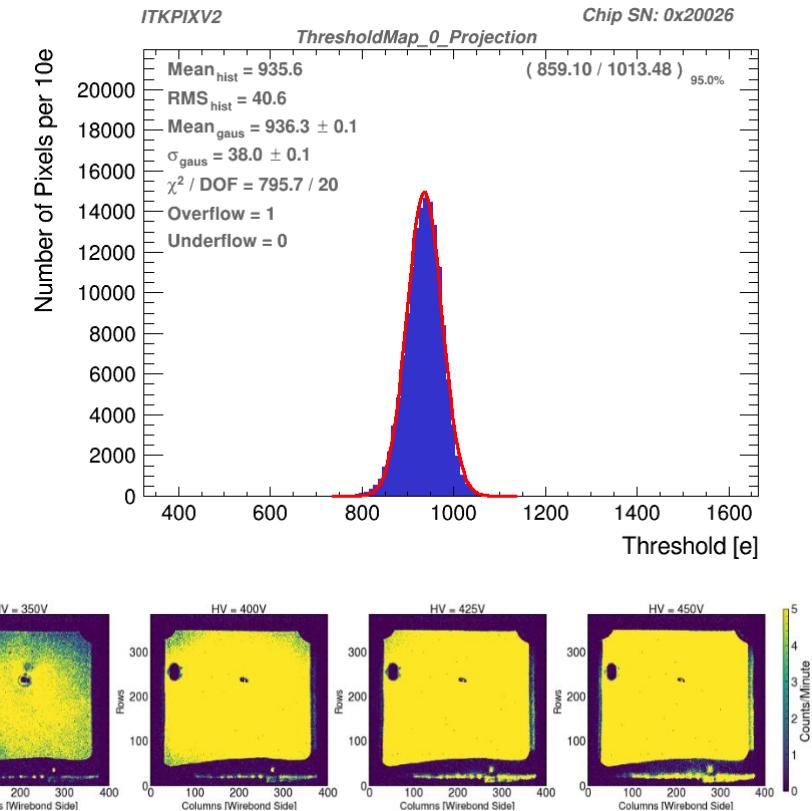
# Research example: thin film detectors

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Selenium is used in flat panels for x-ray detection:  
applications to medical imaging

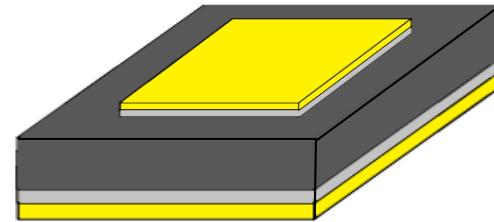
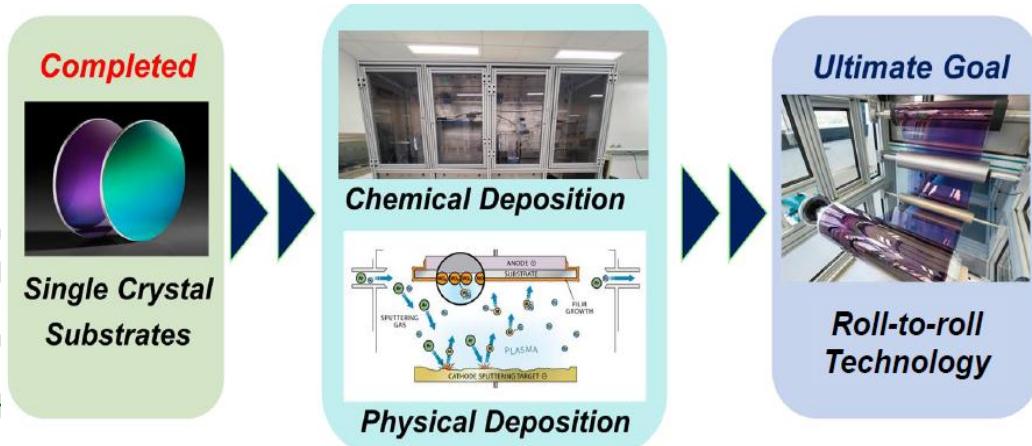
➤ Interdisciplinary / cross-cutting research!



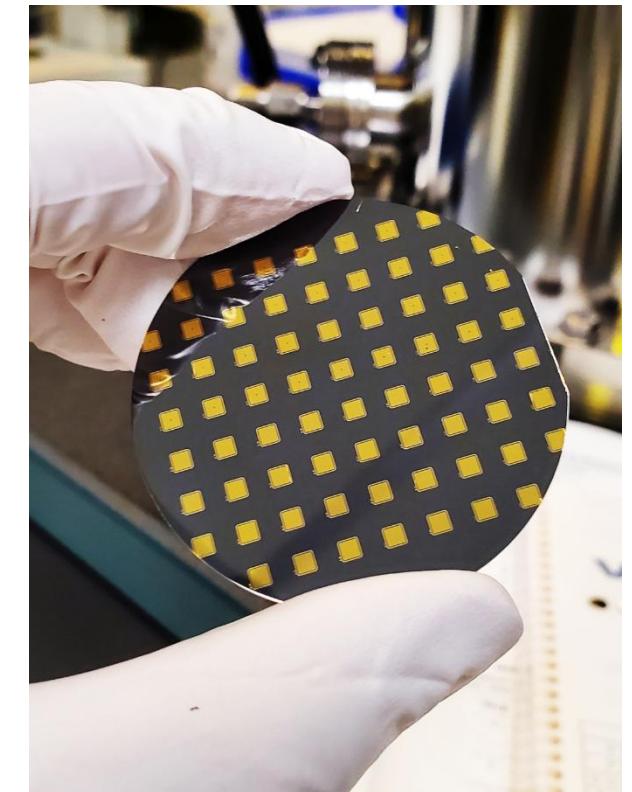
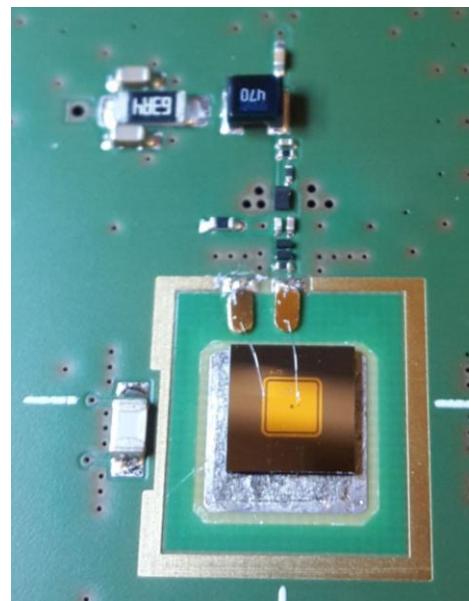
# Research example: InP

Indium phosphide: compound semiconductor with very high electron mobility

- Reference samples fabricated on crystalline substrates; goal is large-area deposition as thin films
- Studies on timing resolution and radiation hardness



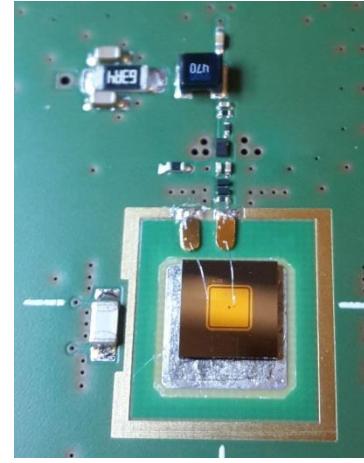
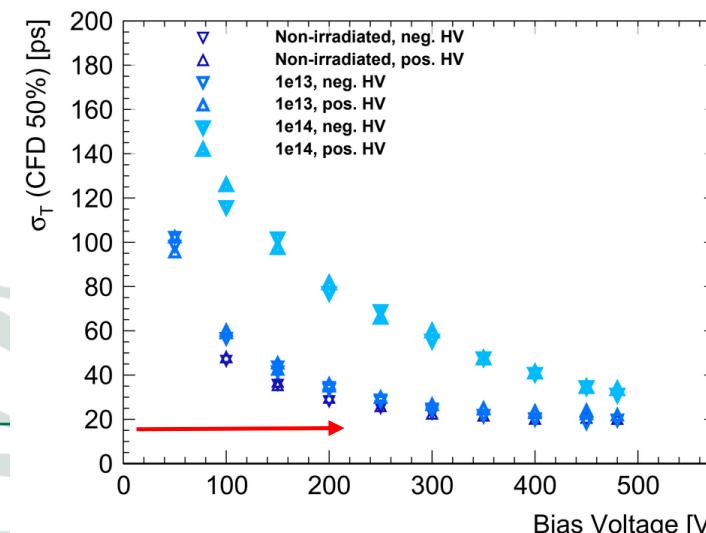
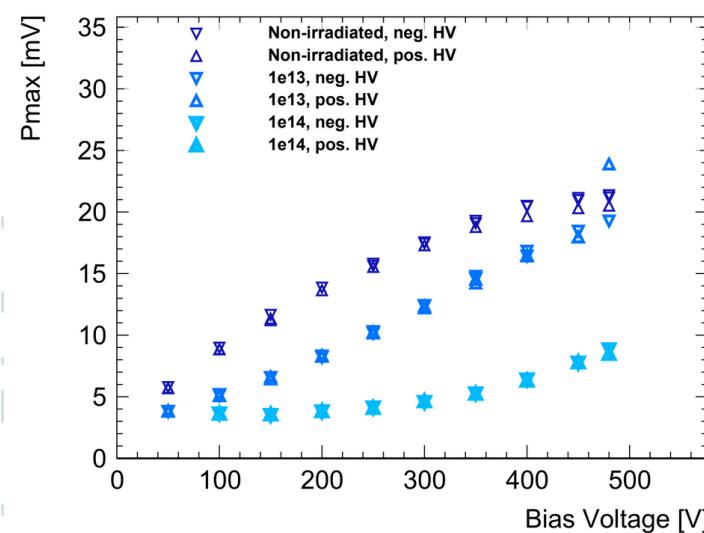
Gold (100 nm)  
Chromium (10 nm)  
InP:Fe (350  $\mu$ m)  
Chromium (10nm)  
Gold (100 nm)



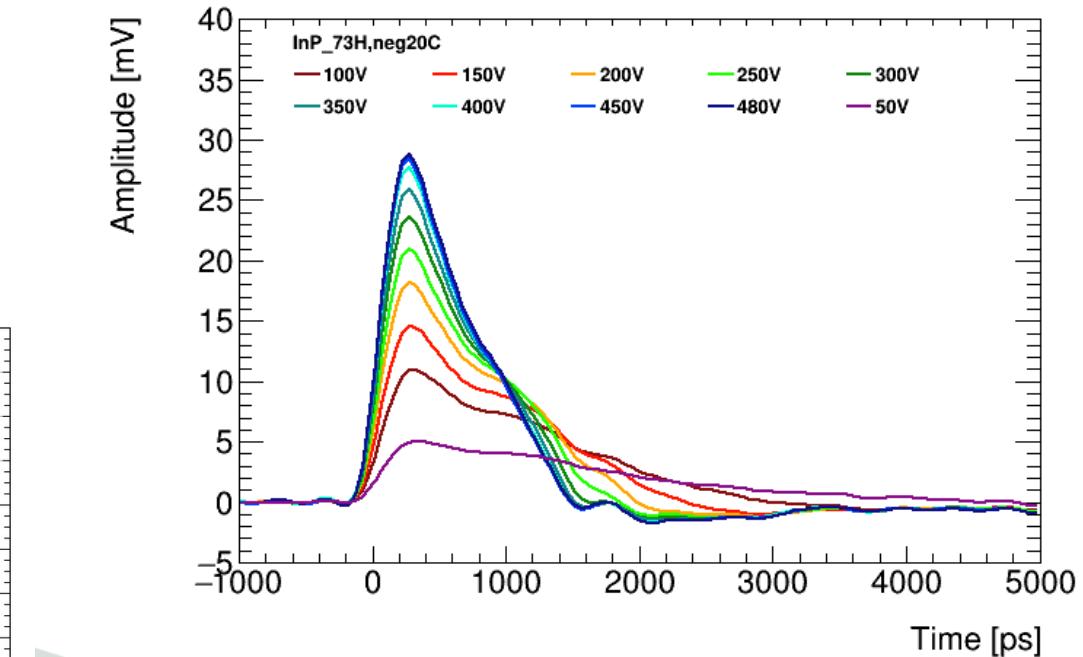
# Research example: InP

Indium phosphide: compound semiconductor with very high electron mobility

- Reference samples fabricated on crystalline substrates; goal is large-area deposition as thin films
- Studies on timing resolution and radiation hardness



< 1-2 ns signal collection



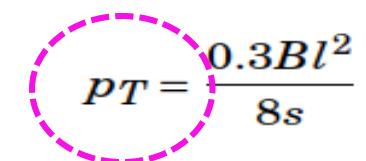
Retaining excellent timing resolution

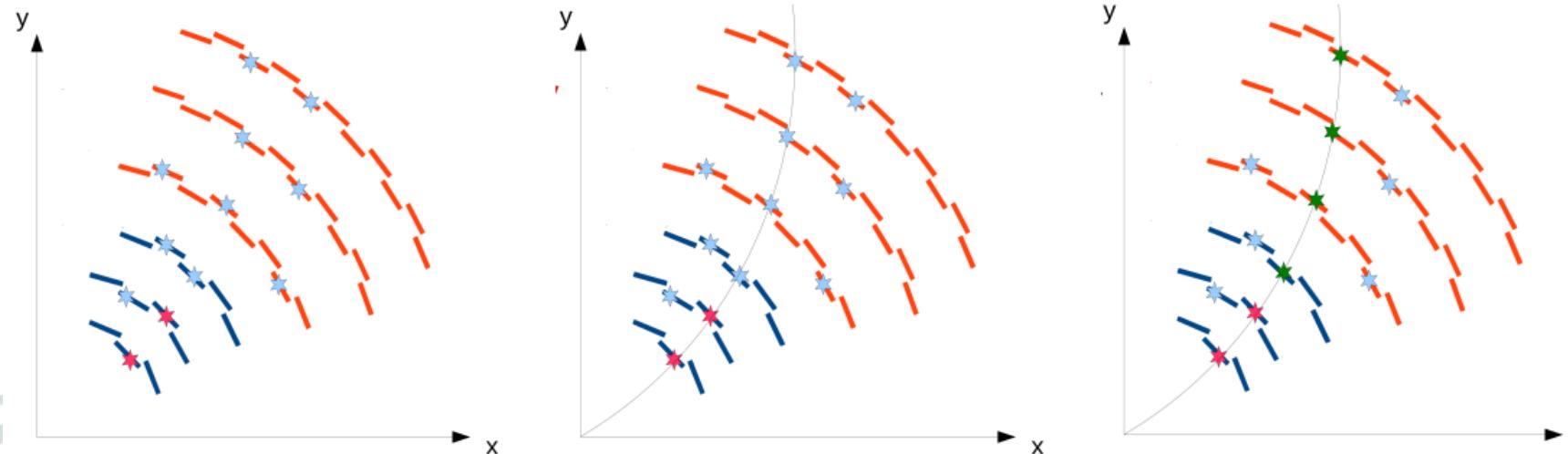
# Tracking detectors ...

Objective: determine the 'path' of a particle → calculate its momentum

In a magnetic field, charged particles are deflected:

$$\mathbf{F}_L = \frac{d\mathbf{p}}{dt} = q\mathbf{v} \times \mathbf{B}$$

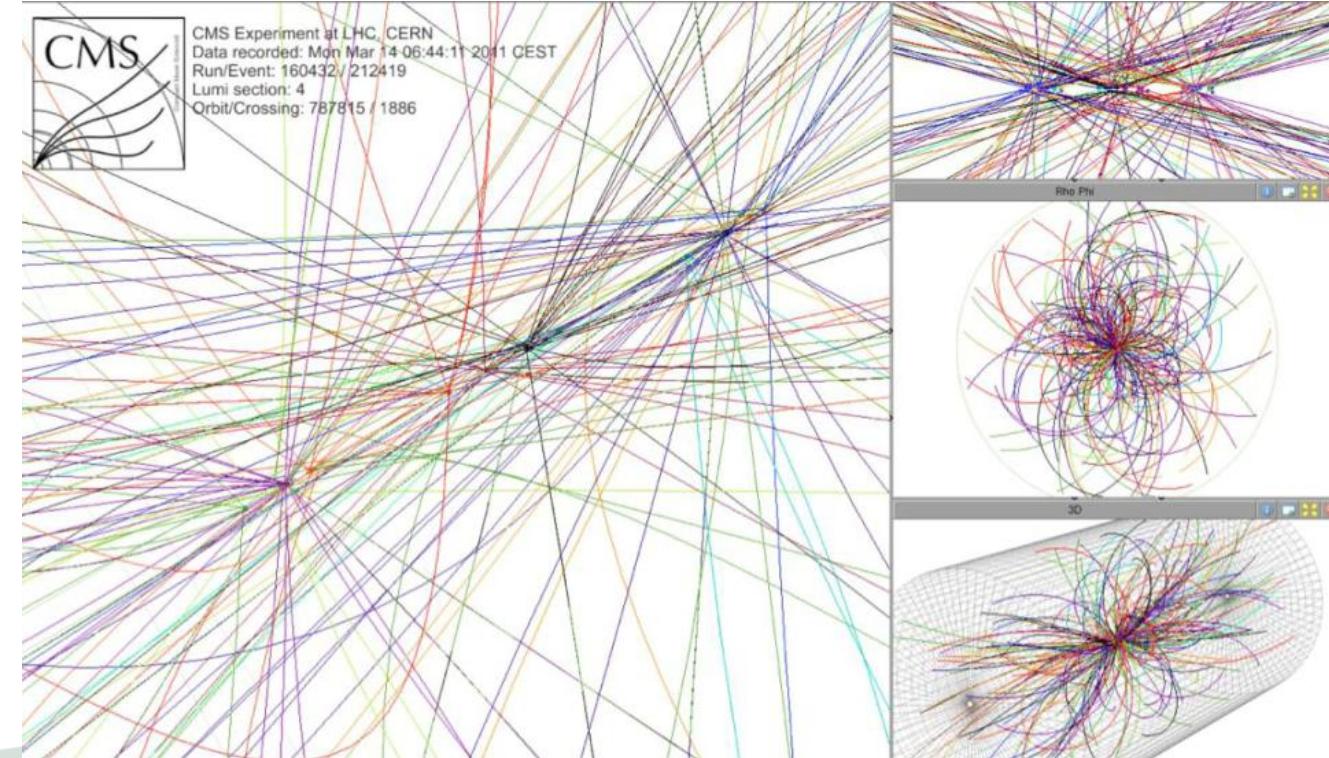
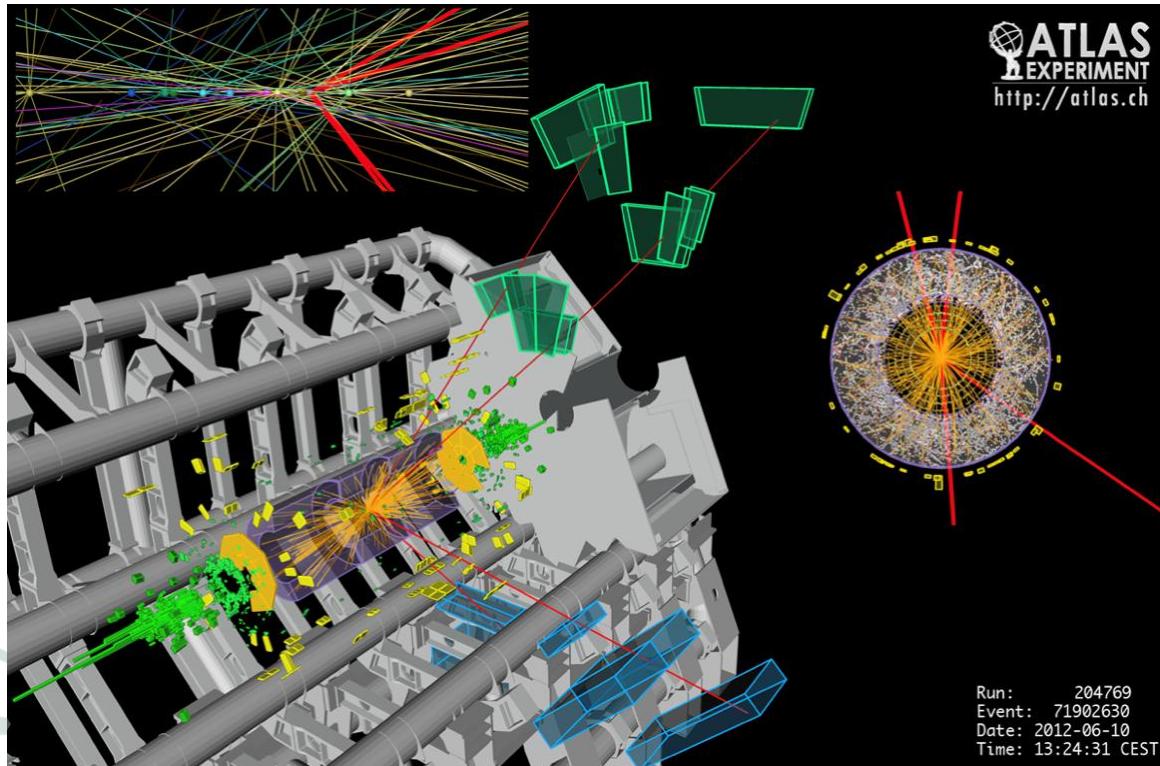

$$p_T = \frac{0.3Bl^2}{8s}$$



# Particle tracking and vertexing

Several collisions per bunch crossing:

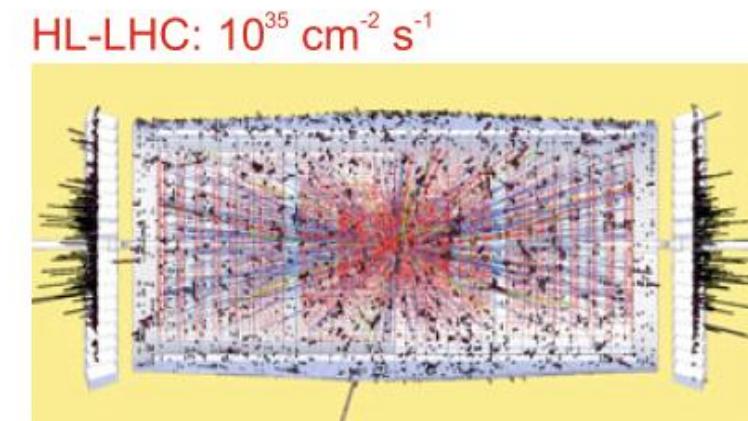
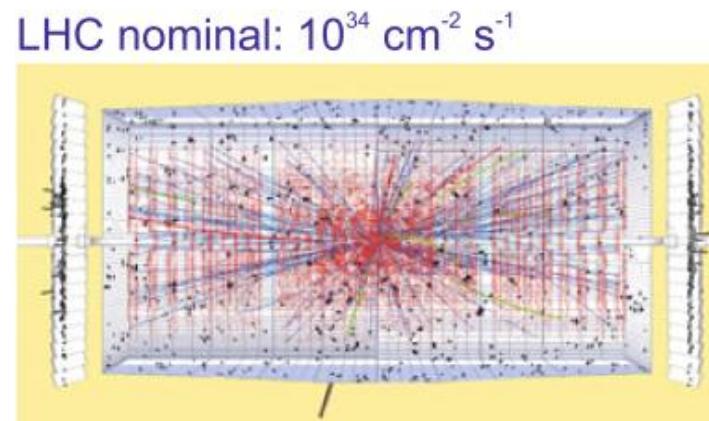
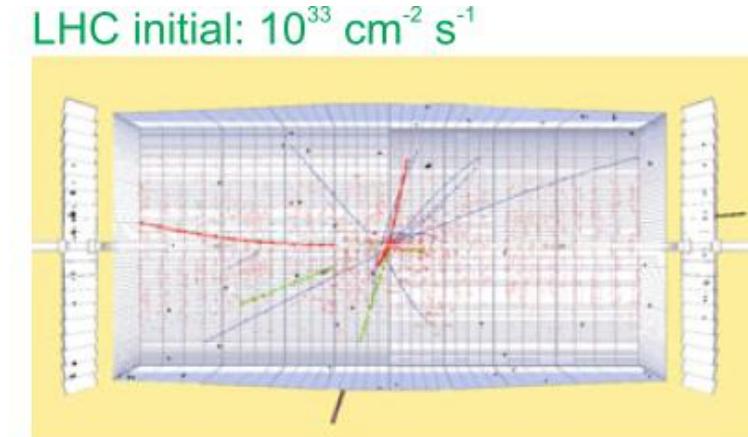
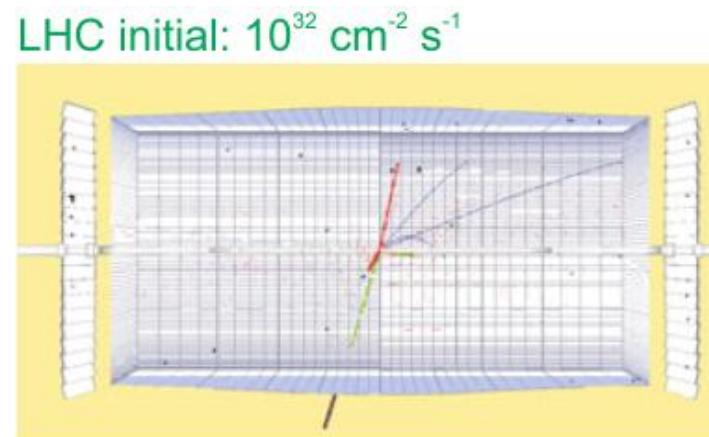
→ vertexing: point / associate a track to the original interaction point



# Precision timing

At the HL-LHC, the number of interactions per bunch crossing, i.e. *pile-up* increases from  $\sim 50$  to  $\sim 200$

- *Timing resolution of 30-60 ps is needed to associate tracks to primary vertex (and improves many analyses performances)*



# Timing detectors at the HL-LHC

**Largest targeted efforts in fast sensor development: Phase-2 upgrades of ATLAS and CMS experiments at the LHC for the HL-LHC**

- Bunch crossing frequency: 40 MHz = 25 ns
- p-p collision center-of-mass energy up to 14 TeV
- Schedule: HL-LHC planned to (re)start **in 2030 -> timing detector production and installation after 2028**
- Main objective: pileup mitigation, retaining it at the level of the current LHC (~30)
- Radiation hardness in a proton-proton collision environment:  $2 \times 10^{14} - 2 \times 10^{15} n/cm^2$
- Timing layers are new detector systems; located between Si tracker and EM calorimeters

# Precision timing

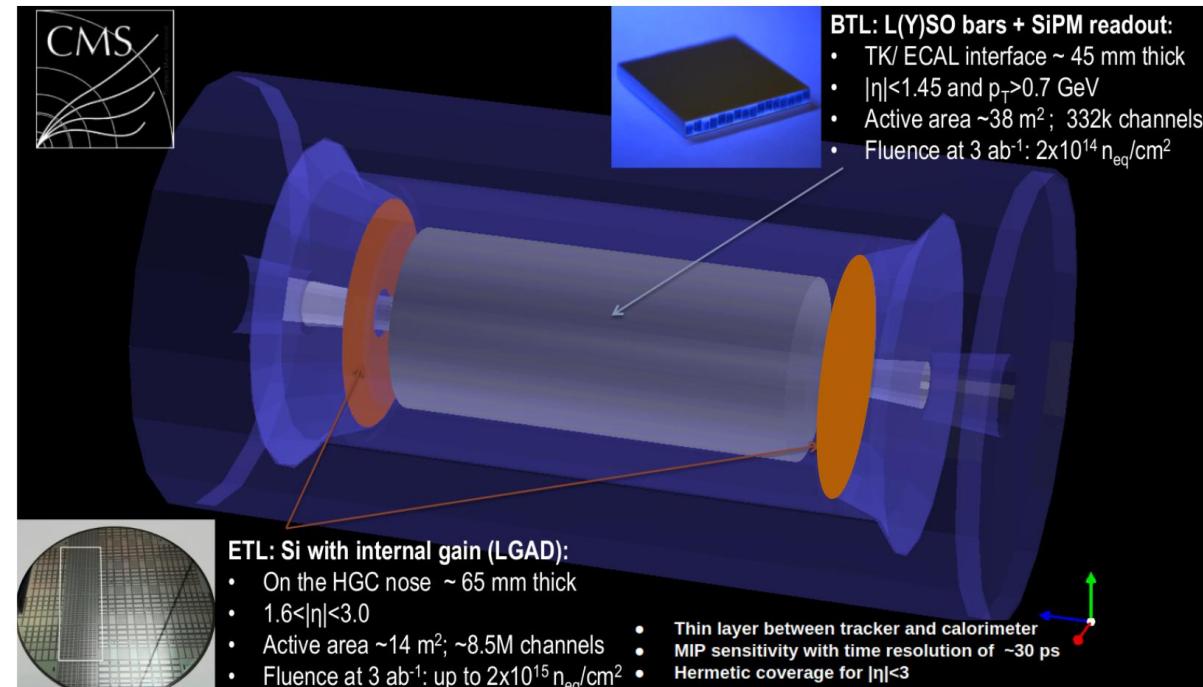
**CMS and ATLAS experiments will install dedicated MIP timing detector layers in the Phase-2 upgrades, between tracking systems and calorimeters**

## CMS

- Barrel and endcap region with different technologies: barrel scintillators + SiPM, endcap with fast silicon detectors – **LGADs**

## ATLAS

- Timing detectors only in the endcap region, with **LGADs**



CMS MTD Technical Design report

# Precision timing

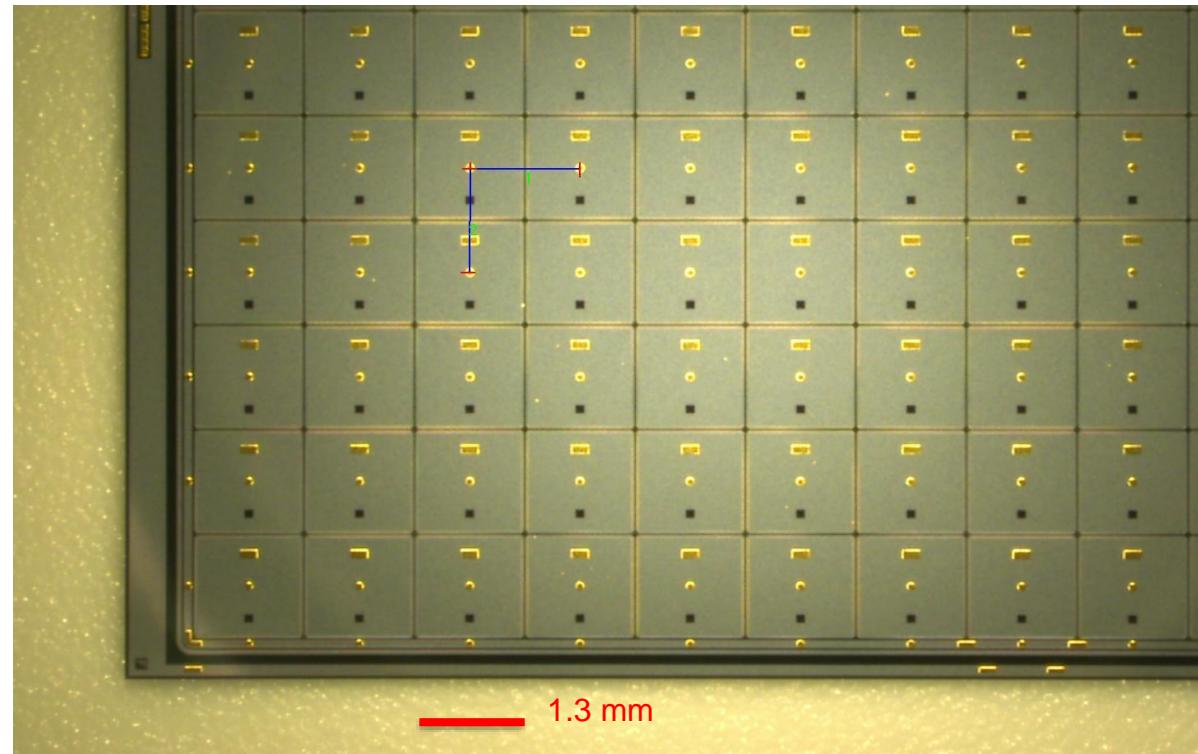
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## CMS

- Barrel and endcap region with different technologies: barrel scintillators + SiPM, endcap with fast silicon detectors – **LGADs**

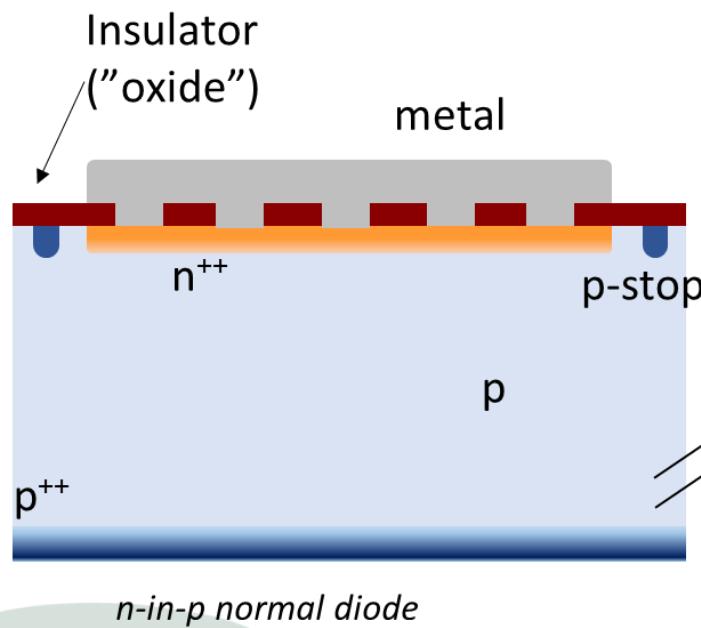
## ATLAS

- Timing detectors only in the endcap region, with **LGADs**

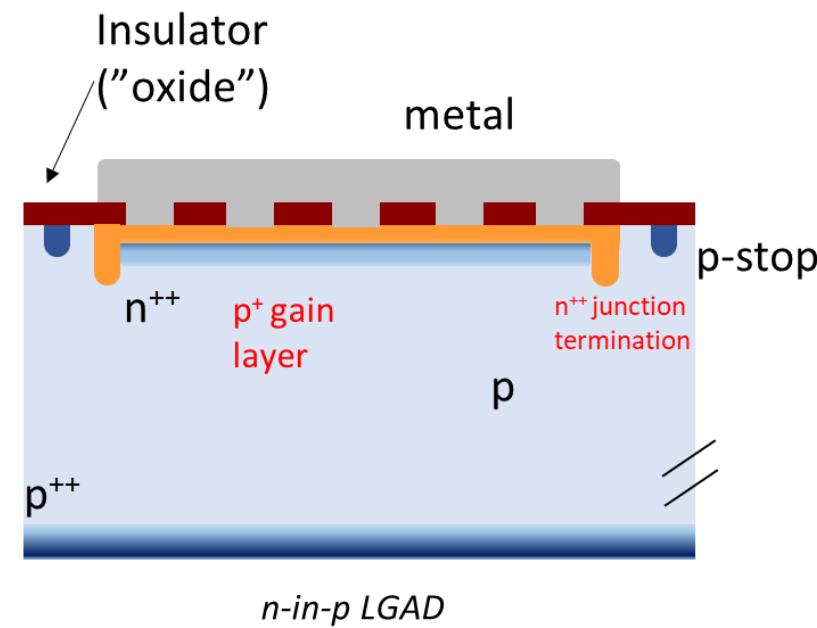


# Low-gain avalanche diodes

Multiplication layer implanted with higher doping concentration – localized high electric field leads to impact ionization of secondary charge carriers



*n-in-p* normal diode

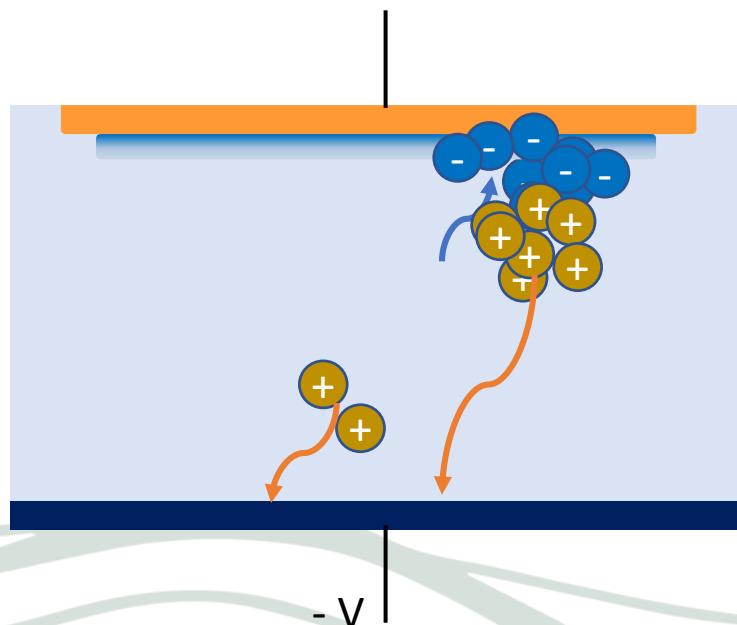


*n-in-p* LGAD

e.g. H. F.-W. Sadrozinski et al, 4D tracking with ultra-fast silicon detectors, Reports on Progress in Physics 2018, 81, 026101

# Low-gain avalanche diodes

- Gain layer with moderate doping concentration (lower than  $n^{++}$  or  $p^{++}$  contacts) results in localized, higher electric field
- Electrons reach enough kinetic energy to ionize other atoms in the Si lattice – multiplication, ‘avalanche’



1. Electrons drift to the segmented electrode and pass by the gain layer
2. Holes drift to backplane
3. Electrons generate new e-h pairs at the gain layer
4. New electrons only drift a few  $\mu\text{m}$  to the front electrode: are typically obscured by rise time of the electronics
5. **New holes drift through the bulk to the backplane**

# Low-gain avalanche diodes

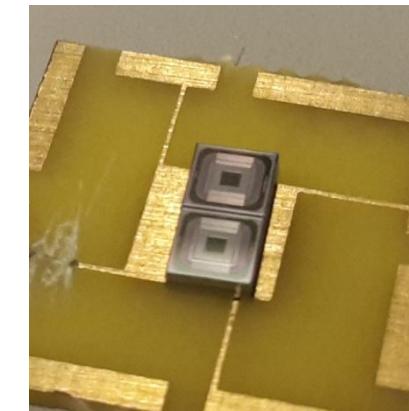
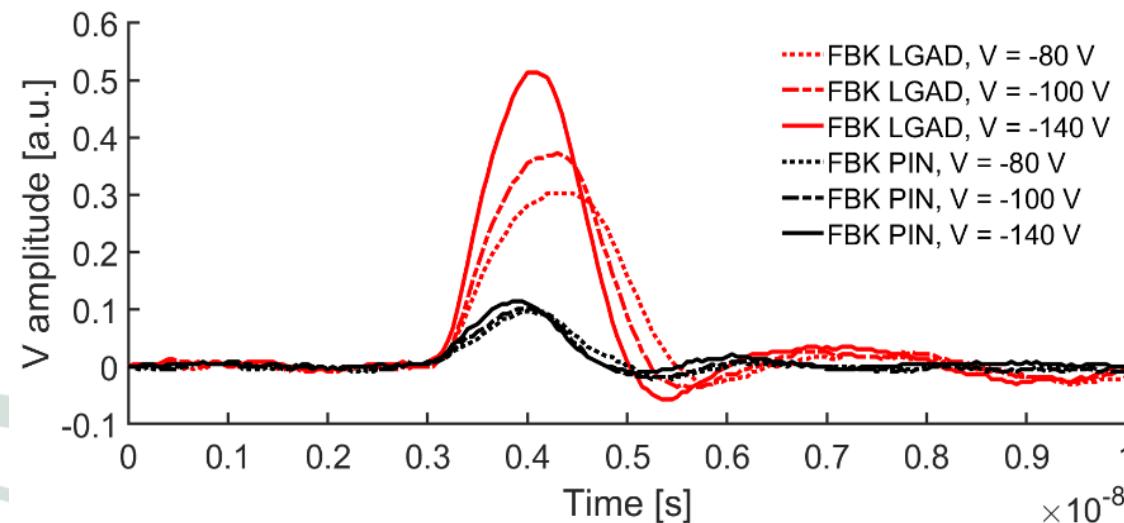
Thin sensors, typical active thickness 50  $\mu\text{m}$  – shorter drift time, higher electric field, less Landau fluctuations!

- Mechanical support wafer 150-400  $\mu\text{m}$ !

Low to moderate gain (5-50) provided by p<sup>+</sup> multiplication layer

Timing resolution down to ca. 20 ps

Good radiation hardness up to  $10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

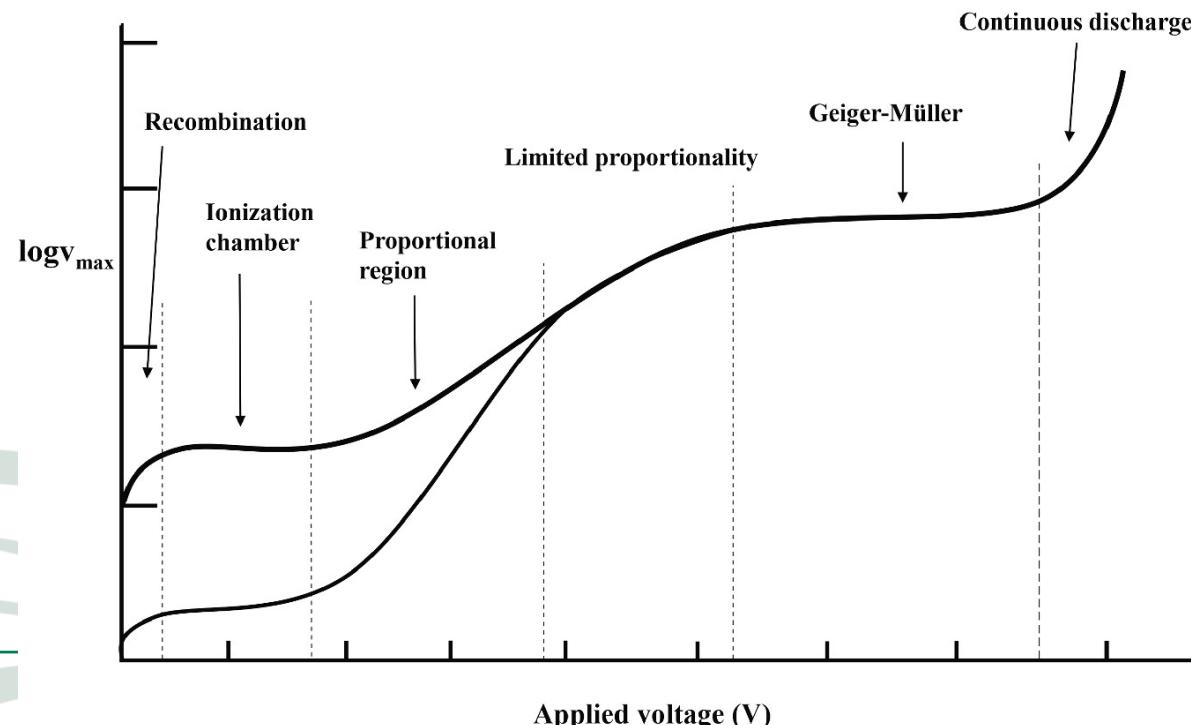


Gain determination with LGAD-diode pairs in laser TCT

# Low-gain avalanche diodes

Multiplication layer implanted with higher doping concentration – localized high electric field leads to impact ionization of secondary charge carriers

***Difference to SiPM: only primary electrons are multiplied***



# Low-gain avalanche diodes

Multiplication layer implanted with higher doping concentration – localized high electric field leads to impact ionization of secondary charge carriers

***Difference to SiPM: only primary electrons are multiplied***

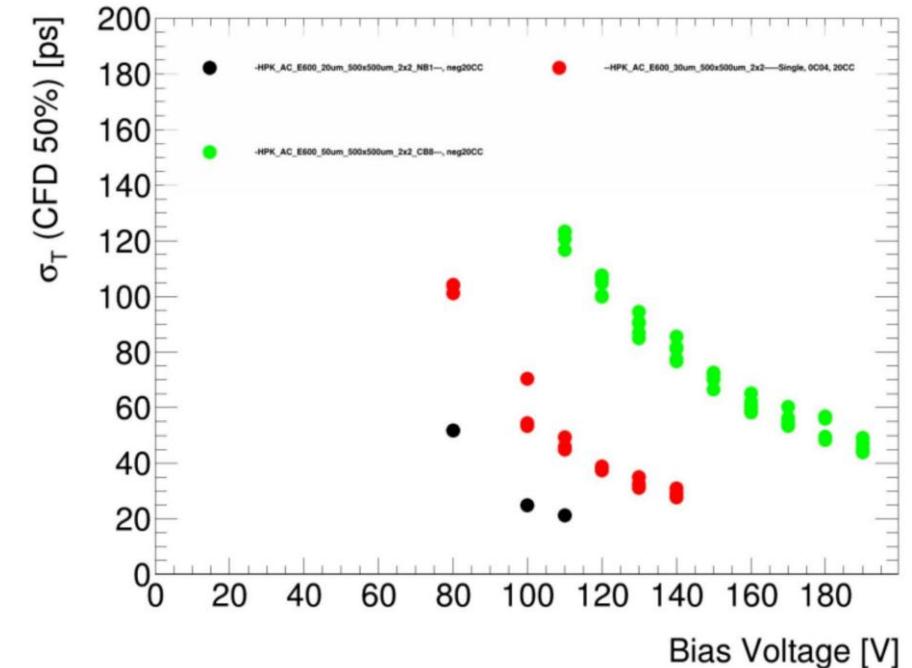
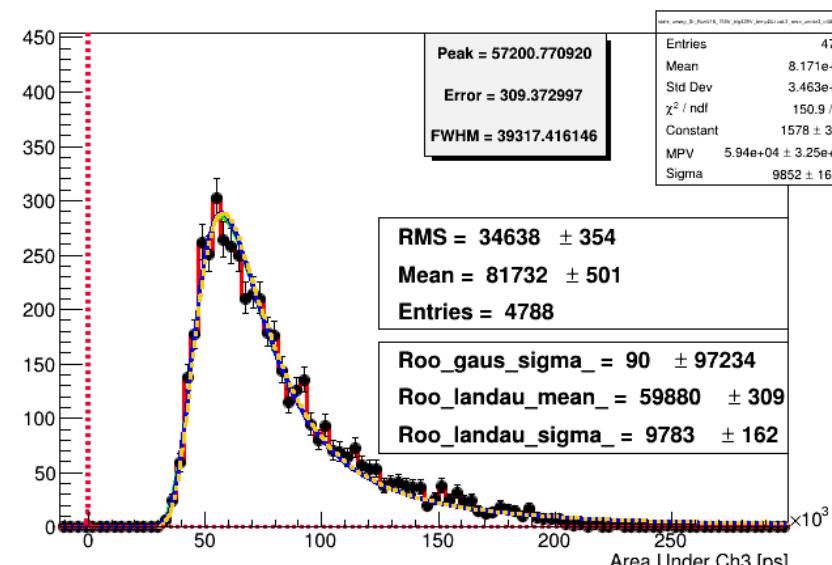
- Sensor is in proportional mode, not in Geiger mode reaching saturation for each photoelectron
  - Low to moderate gain of ca. 5 – 50
  - Spatial resolution is determined by electrode segmentation, like a standard planar Si sensor
- Slower onset of gain, increase with bias voltage
  - Operation voltage and breakdown depends on desired gain, gain layer and sensor edge architecture: 150 – 450 V
- *Directly detecting charged particles, not photons: no optimization of surface to reduce light reflection, external quantum efficiency not considered*

# Timing resolution

$$\sigma_t^2 = \sigma_{Landau}^2 + \sigma_{time\ walk}^2 + \sigma_{jitter}^2 + \sigma_{TDC}^2$$

## Timing resolution consists of several contributions

- Landau fluctuations of charge deposition: reduce by thinner sensor
- Time walk
- Jitter (sensor & electronics)
- TDC



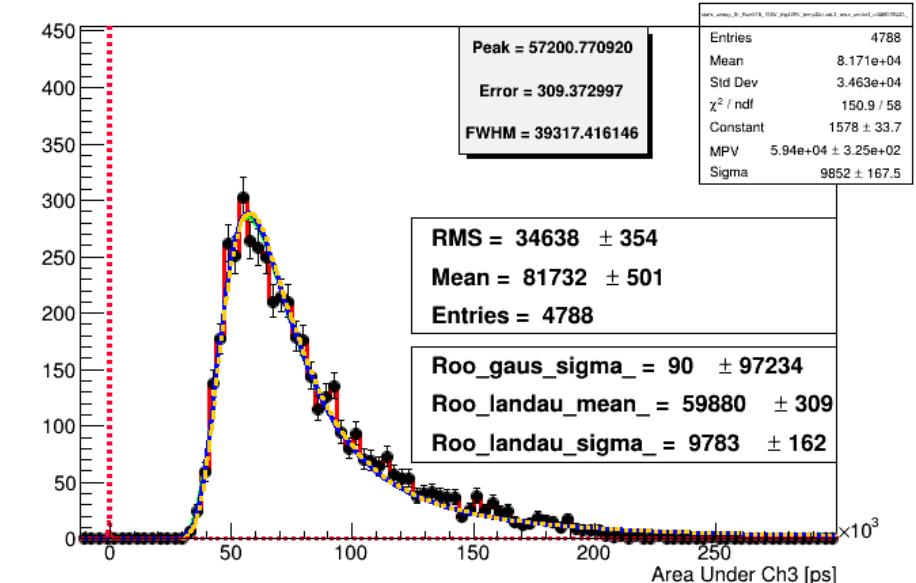
# Timing resolution

$$\sigma_t^2 = \sigma_{Landau}^2 + \sigma_{time\ walk}^2 + \sigma_{jitter}^2 + \sigma_{TDC}^2$$

## Timing resolution consists of several contributions

- Time walk: can be corrected for
- Jitter (sensor & electronics)
- TDC
- **Landau fluctuations of charge deposition: lowered by reducing the amount of material traversed, i.e. using thin sensors**
  - ‘Standard’ LGAD active thickness 50  $\mu\text{m}$
  - Also results in shorter drift time and higher electric field at the same absolute voltage

*For handling reasons in fabrication – bonding or epitaxial growth of active Si on a low-resistivity mechanical support wafer, 150-400  $\mu\text{m}$ !*

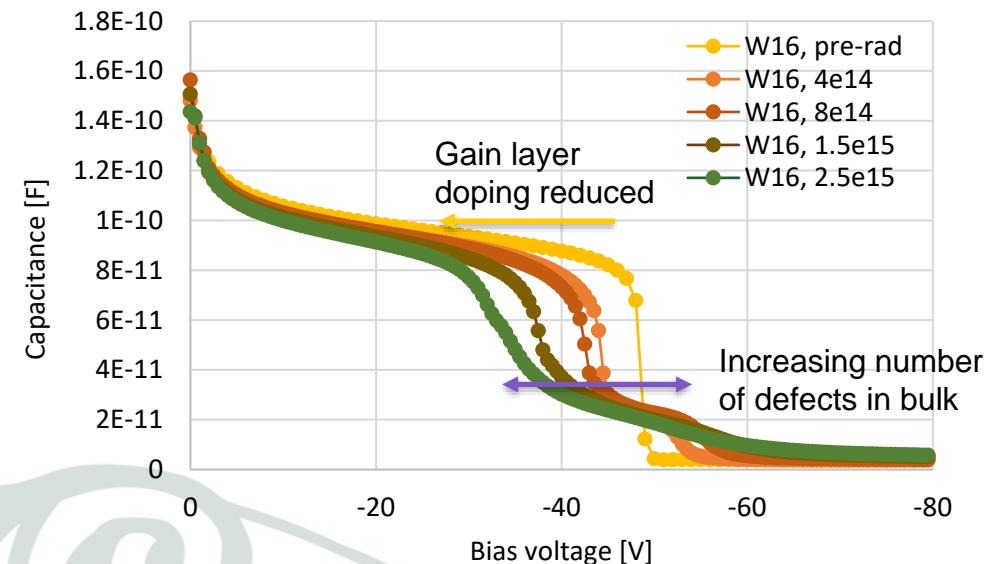


# Radiation damage in LGADs

LGADs (regardless of what structural variant) suffer from degradation of the gain due to deactivation of acceptors

Can be addressed to some extent by gain layer and defect engineering:

- Different dopant: e.g. Ga instead of B
  - Not successful
- **Carbon co-doping**
  - **Successful at reducing gain layer deactivation**
- Partially activated boron
  - More recent; very mixed results for different vendors



# Fast timing at other colliders

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*No connection to nuclear power or nuclear weapons...*

# Motivation: nuclear physics experiments

Nucleon and nuclei structure, mass and spin; QCD at extreme densities; 'imaging' of nuclei

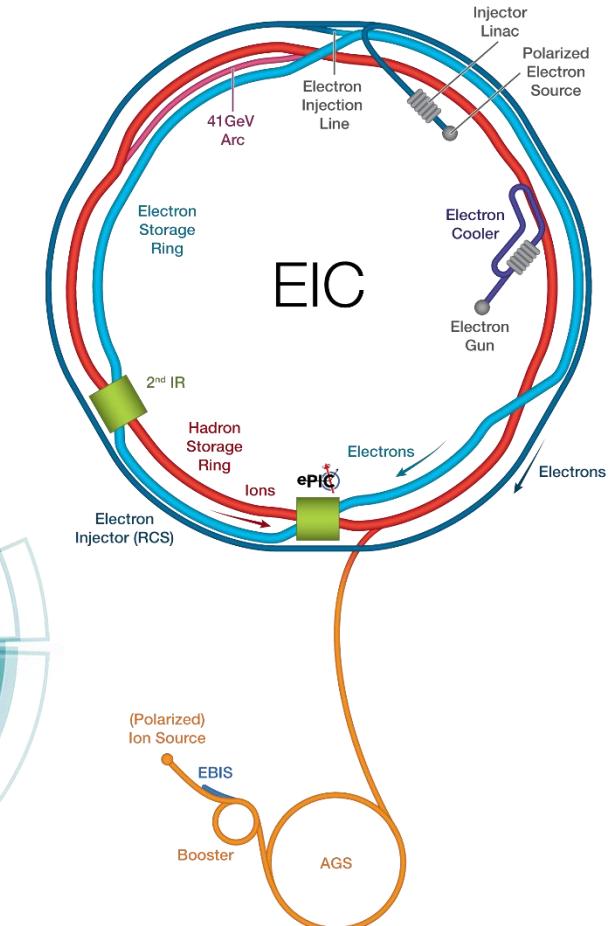
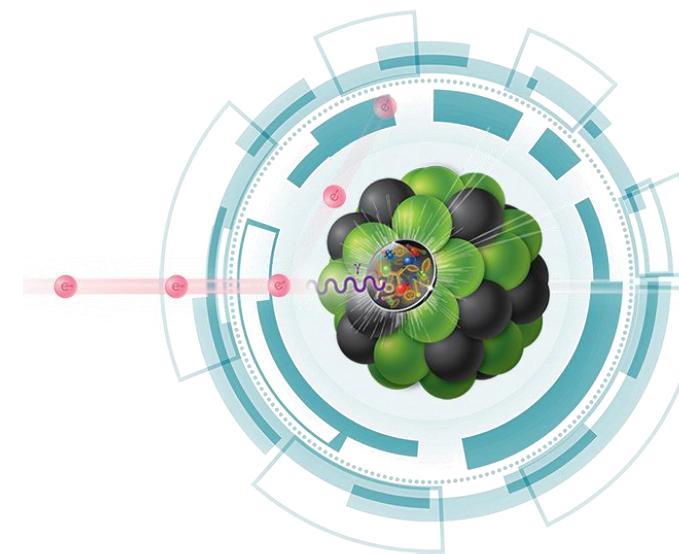
**Electron-Ion Collider:** joint project by Brookhaven and Jefferson National Laboratories

**Operations scheduled to begin 2032-2034**

**Center-of-mass energy: 20 –140 GeV**

- electrons: 2.5 –18 GeV
- protons: 40 –275 GeV (ions:  $Z/A * E_p$ )

**Luminosity:  $2 \times 10^{34} \text{ cm}^{-2}\text{s}^{-1}$**

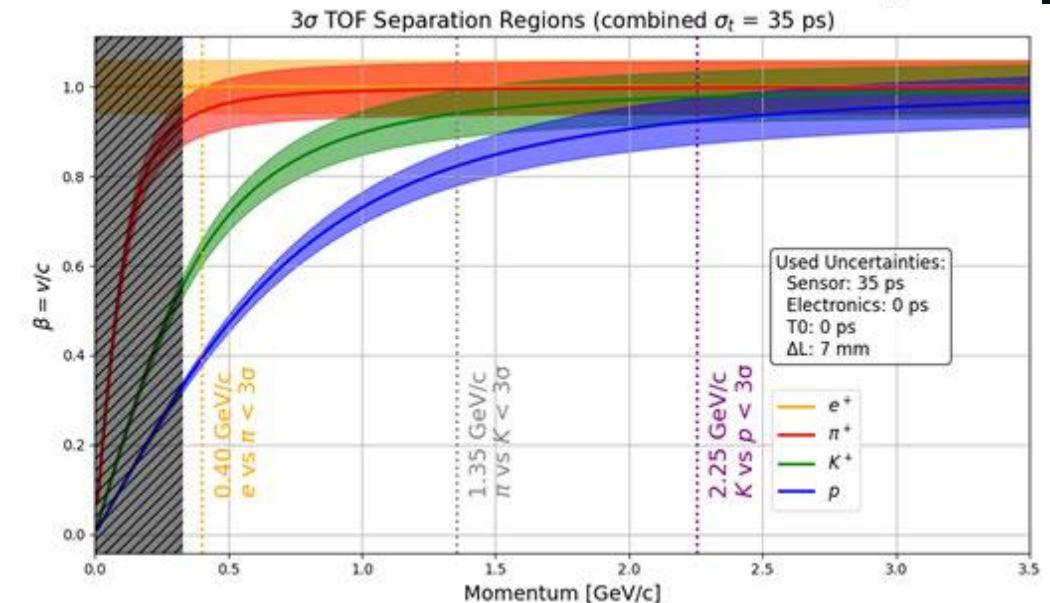
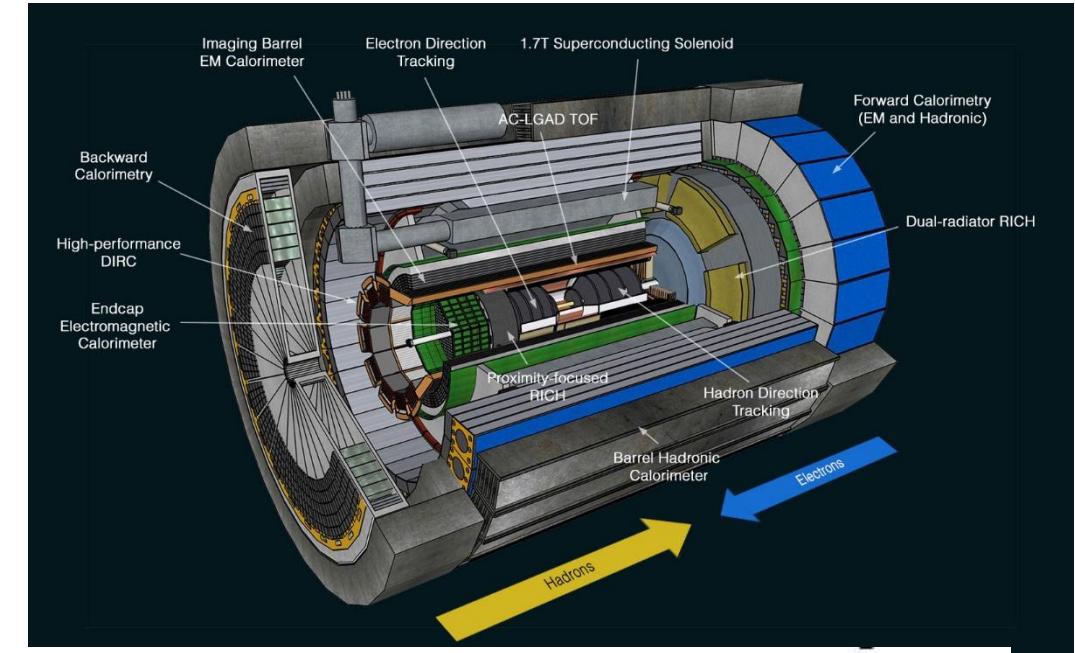


# Particle ID



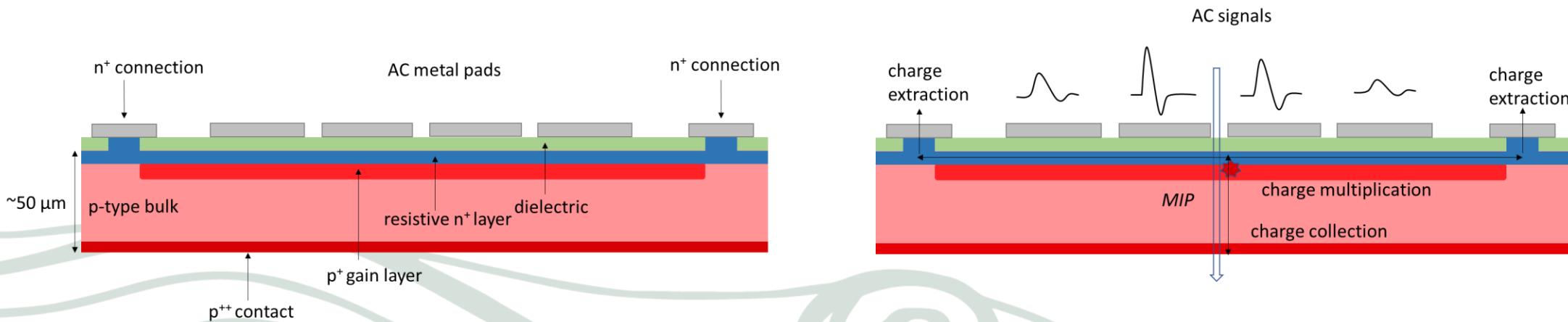
Several detectors for particle ID in inner or outer barrel layers, hadronic endcap, electron endcap

- Momentum and rapidity range cannot be covered by a single technology
  - Leveraging variants of Cherenkov detectors
- Time-of-flight particle ID layer: silicon AC-LGADs
- $T_0$  timestamp(?)
- Additional layer in tracking
- AC-LGADs replaced by picosecond photodetectors in electron (backward) endcap
  - Excellent performance in distinction of charged particle species at low momenta  $< 3$  GeV



# AC-LGADs

- Also referred to as ‘Resistive Silicon Detectors’ (RSD): more resistive front side n<sup>+</sup> implant than in standard Si sensors
- Continuous dielectric, n<sup>+</sup> implant, and gain layer; patterned metal readout electrodes
  - *No junction termination extension or p-stop between electrodes: fill factor ~100*
  - *Mirroring of charge at the n<sup>+</sup> layer on the metal pads: AC-coupling*
  - *Strong sharing of charge between metal pads*
  - *Extrapolation of position based on signal sharing – finer position resolution for larger pitch, also allowing for more sparse readout channels*



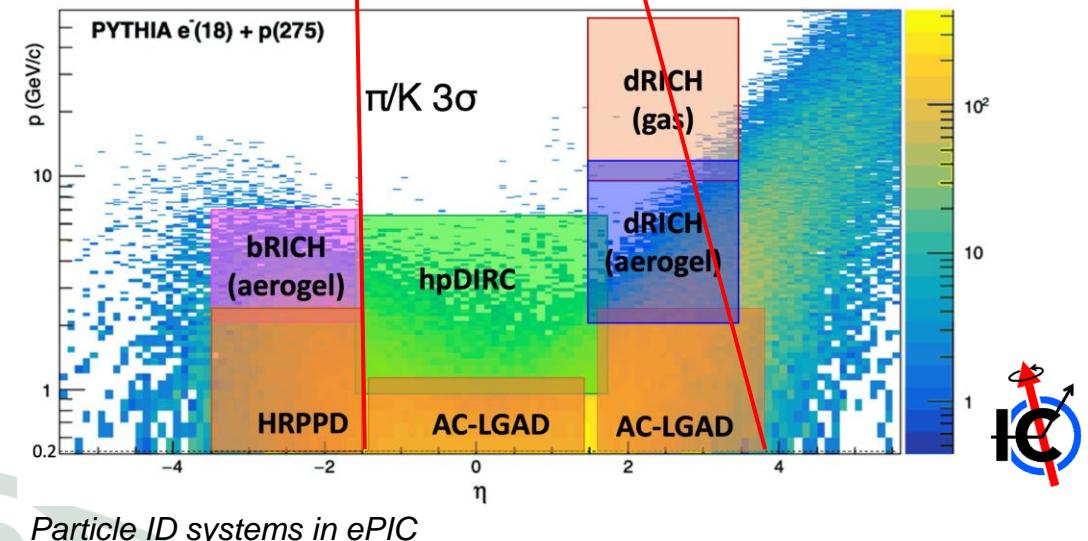
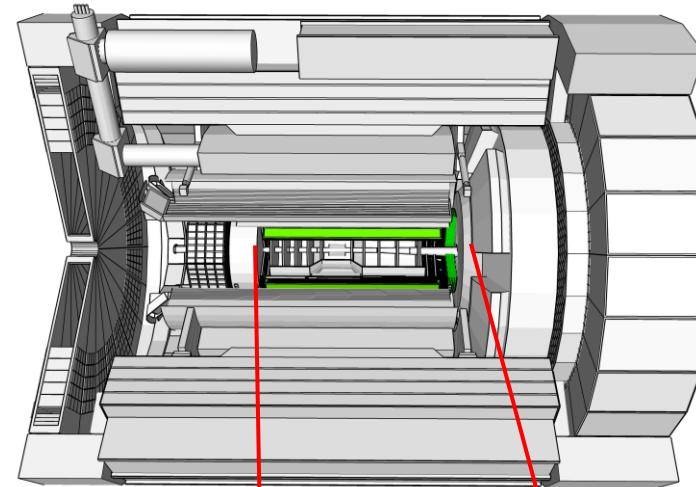
# AC-LGADs in ePIC

## AC-LGAD barrel and forward-endcap Time-of-Flight PID

- Combination of precise temporal and spatial resolution:  
**25 ps and 30  $\mu\text{m}$  / hit**
- Low material budget

## Current sensor design baseline:

- Barrel: **strips, 500  $\mu\text{m}$  pitch and 1 cm length**
- Hadronic endcap (and Roman Pots): **pads, 500 x 500  $\mu\text{m}$**



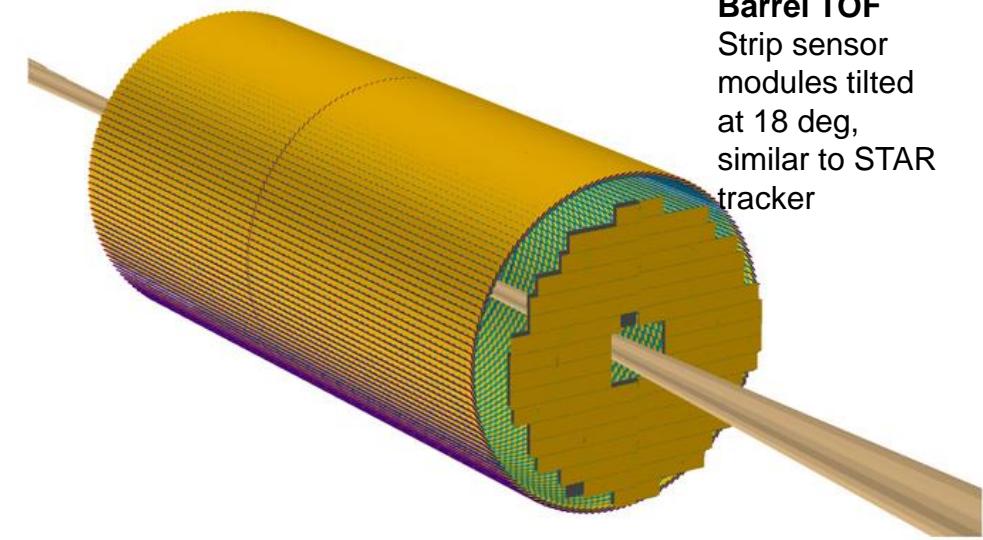
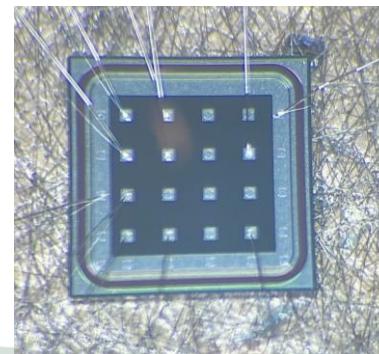
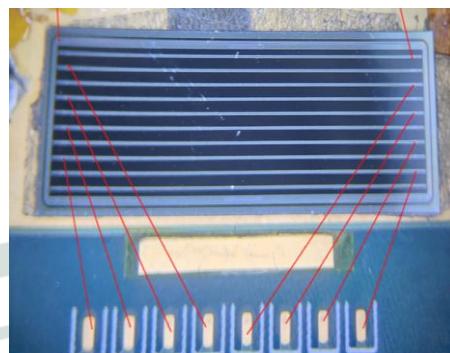
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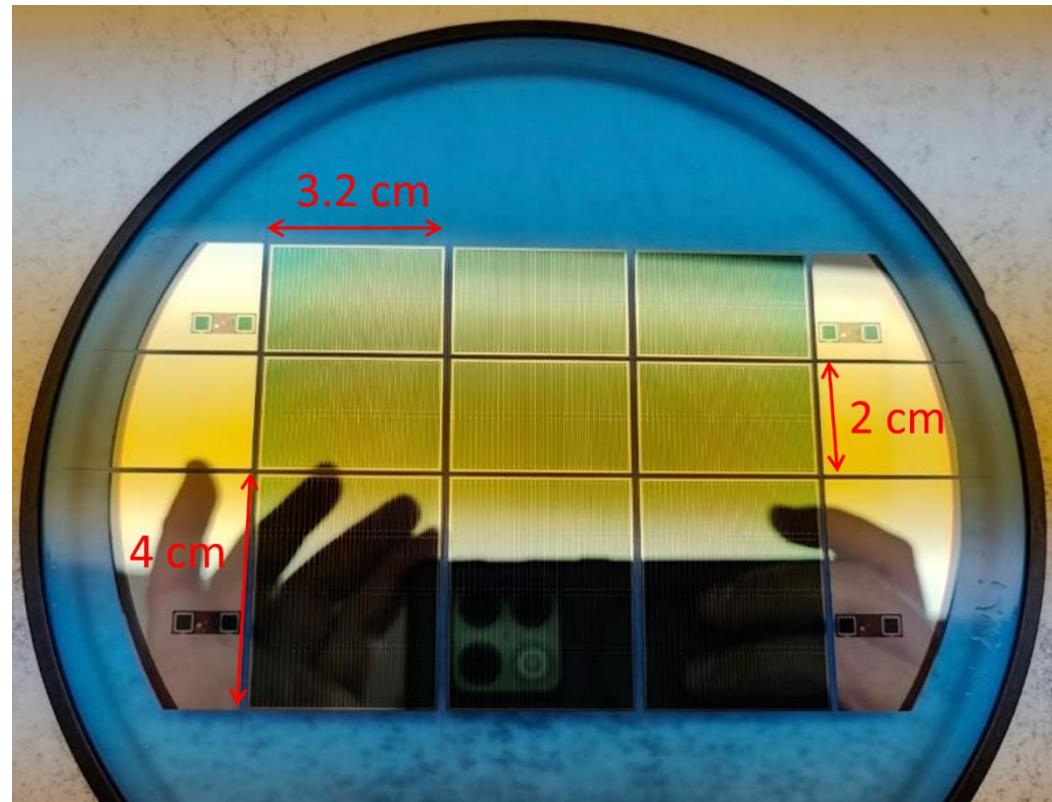
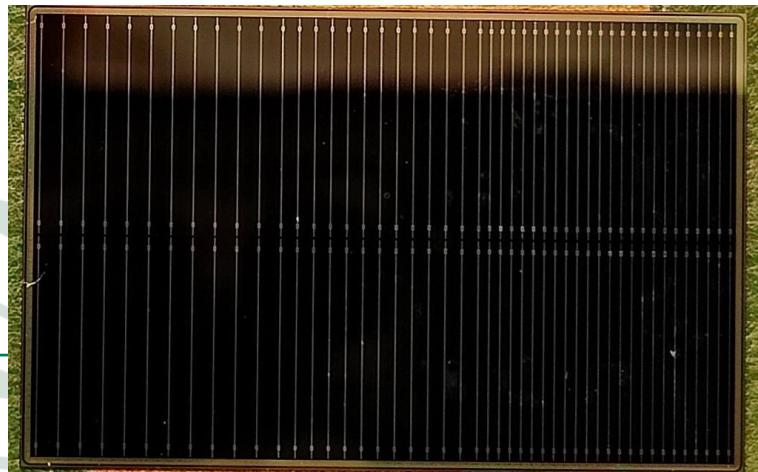
- Barrel: **strips, 500  $\mu\text{m}$  pitch and 1 cm length**
- Hadronic endcap (and Roman Pots): **pads, 500 x 500  $\mu\text{m}$**



# Barrel-TOF current sensor status

## Barrel-TOF, strips:

- Large-area strips received
- 1 cm strip length, two 'sets' of strips on sensor die
  - Can be bonded from either edge
  - Could be 'stitched' together with a wirebond
- Variation of strip pitch
- 30 and 50  $\mu\text{m}$  active thickness



# Flavor physics

Precision measurements at 'lower' energies

➤ on the scale of 10s of GeV

Lepton flavour, LF universality / universality violation: is coupling independent of lepton generation?

Decays of B mesons: production right above mass threshold – lower interference from unrelated background processes

	mass →	charge →	spin →	
QUARKS				
u	$\approx 2.3 \text{ MeV}/c^2$	2/3	1/2	up
c	$\approx 1.275 \text{ GeV}/c^2$	2/3	1/2	charm
t	$\approx 173.07 \text{ GeV}/c^2$	2/3	1/2	top
g	0	0	1	gluon
H	$\approx 126 \text{ GeV}/c^2$	0	0	Higgs boson
d	$\approx 4.8 \text{ MeV}/c^2$	-1/3	1/2	down
s	$\approx 95 \text{ MeV}/c^2$	-1/3	1/2	strange
b	$\approx 4.18 \text{ GeV}/c^2$	-1/3	1/2	bottom
γ	0	0	1	photon
e	0.511 MeV/c <sup>2</sup>	-1	1/2	electron
μ	105.7 MeV/c <sup>2</sup>	-1	1/2	muon
τ	1.777 GeV/c <sup>2</sup>	-1	1/2	tau
Z	91.2 GeV/c <sup>2</sup>	0	1	Z boson
ν <sub>e</sub>	<2.2 eV/c <sup>2</sup>	0	1/2	electron neutrino
ν <sub>μ</sub>	<0.17 MeV/c <sup>2</sup>	0	1/2	muon neutrino
ν <sub>τ</sub>	<15.5 MeV/c <sup>2</sup>	0	1/2	tau neutrino
W	80.4 GeV/c <sup>2</sup>	±1	1	W boson
LEPTONS				
GAUGE BOSONS				

# 4D (5D) tracking: PIONEER experiment

Precision measurement of lepton flavour universality through the charged pion decay branching ratio:

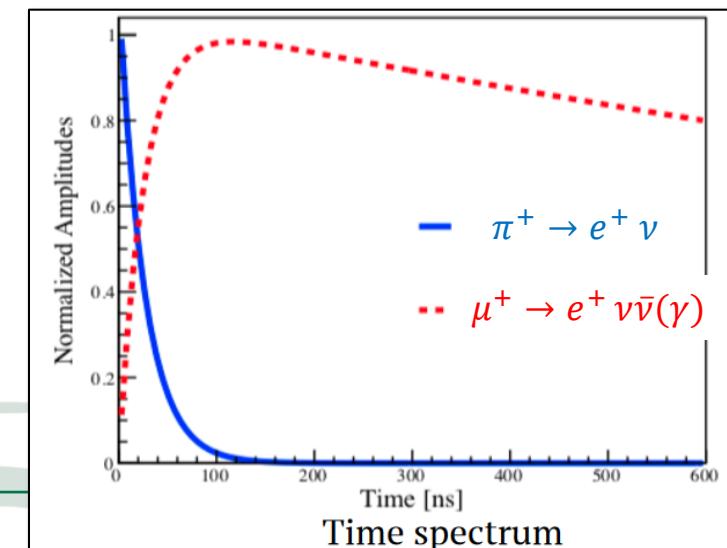
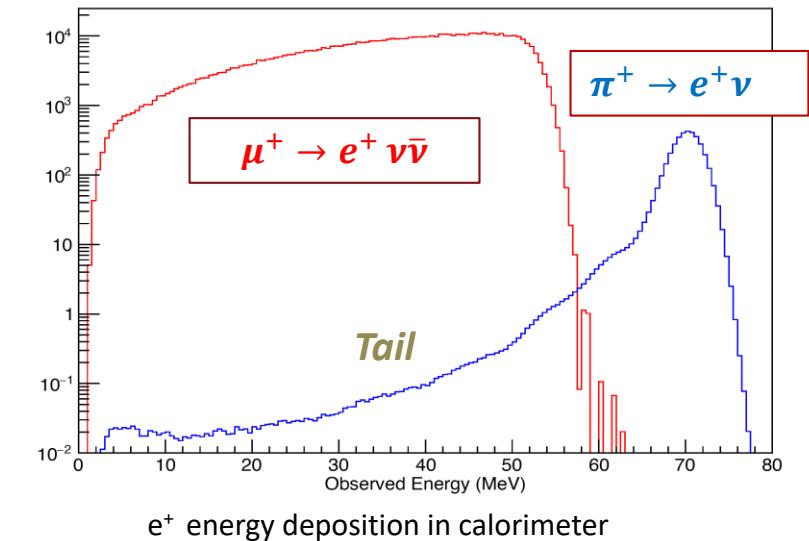
$$R_{e/\mu} = \frac{\Gamma(\pi \rightarrow e\nu(\gamma))}{\Gamma(\pi \rightarrow \mu\nu(\gamma))}$$

$$\pi^+ \rightarrow e^+ \nu(\gamma) \quad 1.23 \times 10^{-4}$$

$$E_e = 69.8 \text{ MeV}$$

$$\begin{aligned} \pi^+ \rightarrow \mu^+ \nu(\gamma) & \quad 99.99\% \\ \mu^+ \rightarrow e^+ \nu\bar{\nu}(\gamma) & \quad 100\% \end{aligned}$$

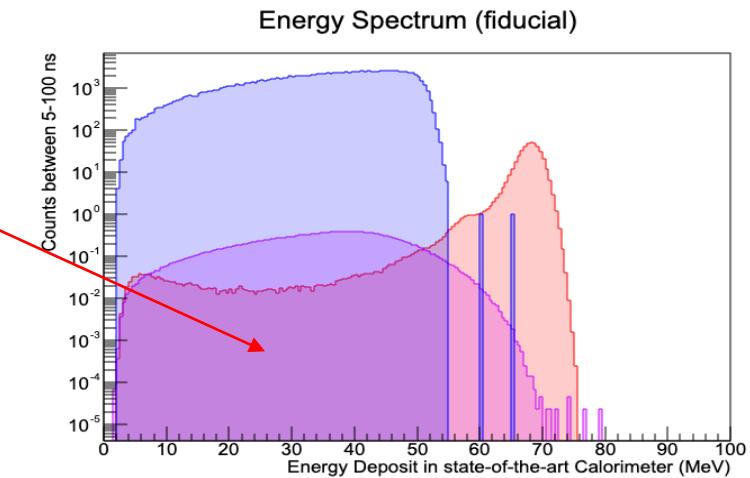
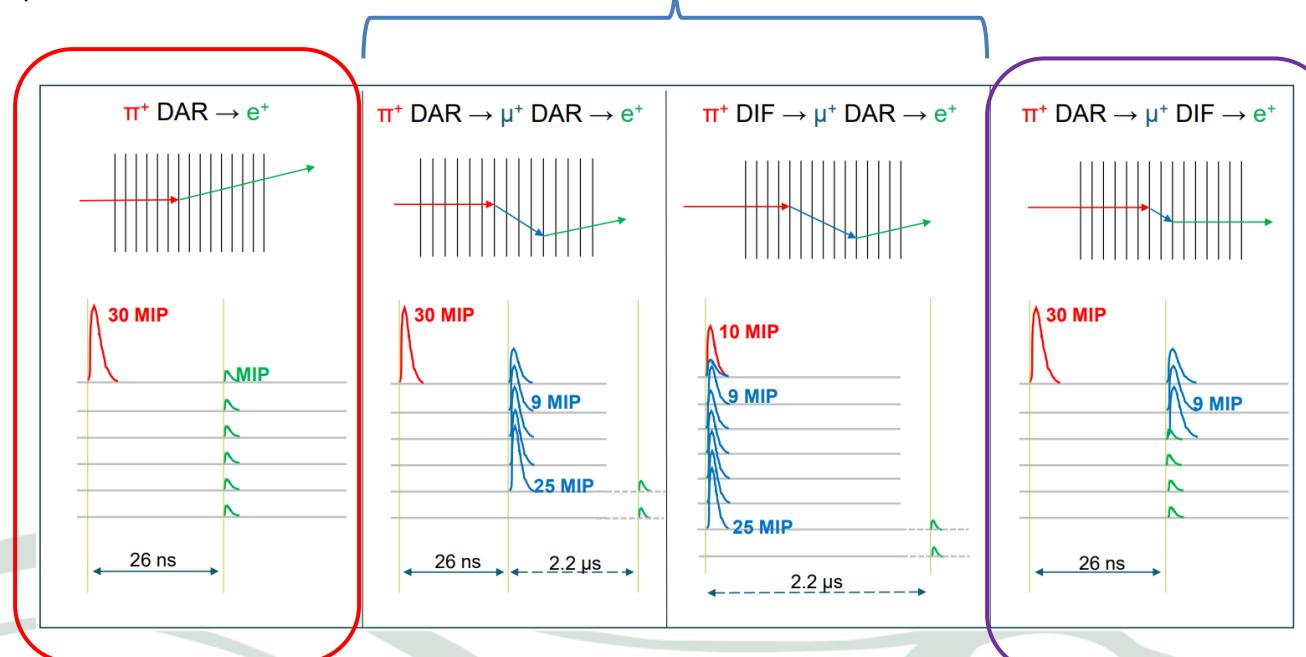
$$E_e = 0.5-52.8 \text{ MeV}$$



# PIONEER: separating muons and positrons

It will be crucial to separate the low-energy tail of  $\pi \rightarrow e$  events from  $\pi \rightarrow \mu \rightarrow e$  decays **in-flight** and **at-rest**

$R_\pi \sim 4$  mm,  $R_\mu \sim 0.8$  mm



# The Active Target detector

5-D tracker can provide rich information (x, y, z, t, E)

## Baseline Technology: low-gain avalanche diodes

- *No-gain option has been / is being explored: requires very low-noise front-end*
- AC-LGADs
- TI-LGADs

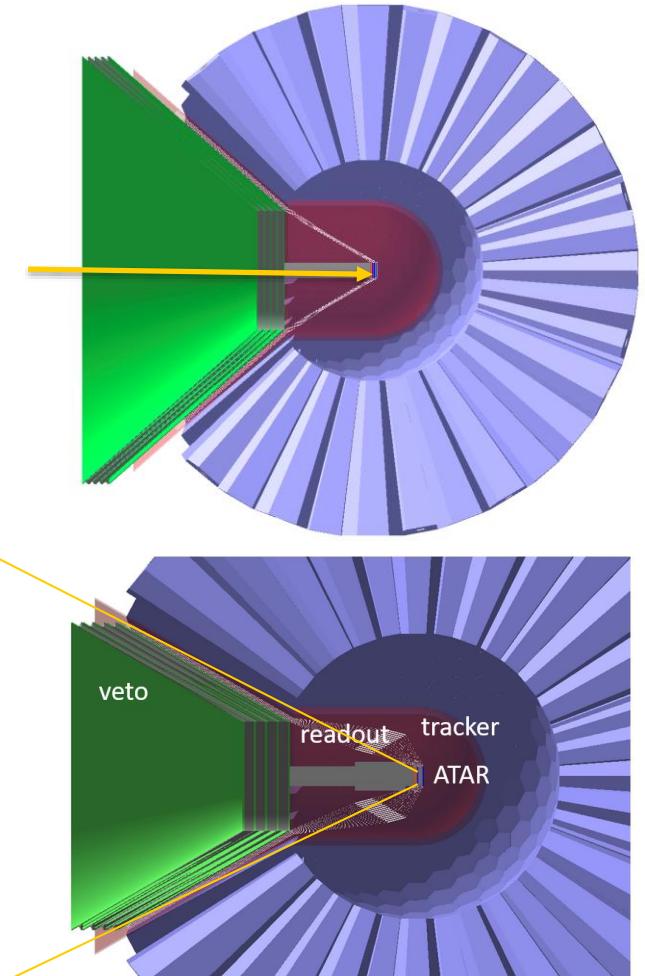
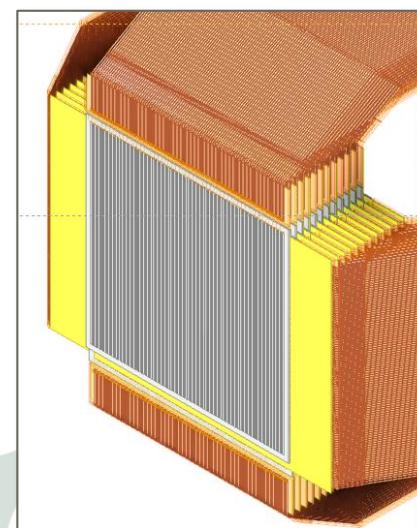
## Dimensions:

- 20 x 20 x 5.76 mm
- 48 sensor layers
- **120  $\mu$ m thickness**, 200  $\mu$ m strips

t:  $\Delta t \sim 200$  ps, pulse pair 2 ns

E:  $\sim 100$  dynamic range,  $\sigma_E < 10$  %

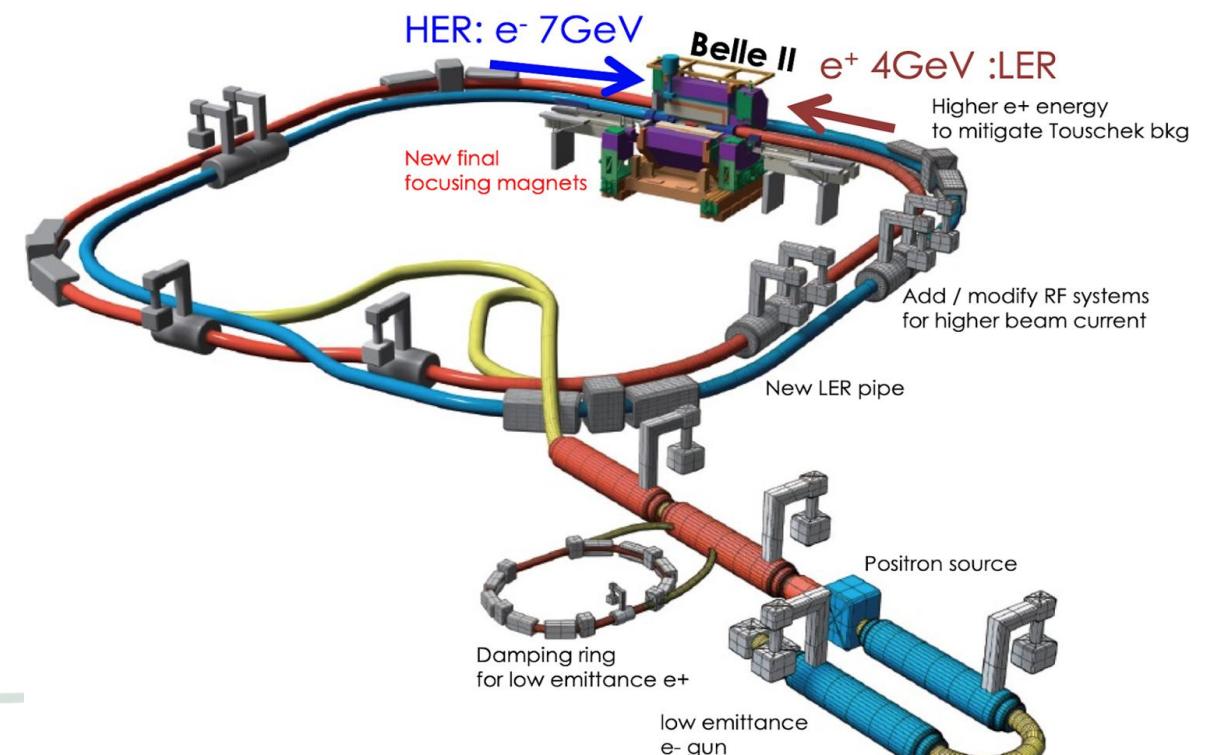
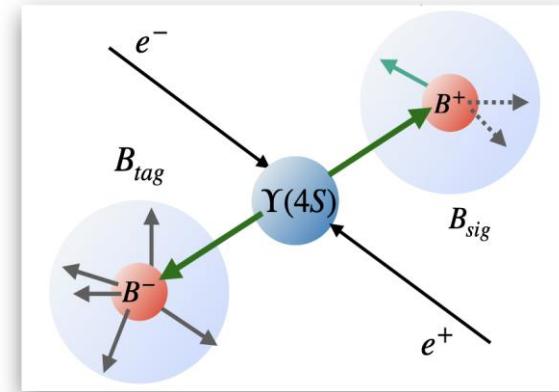
stack: fully active, “no dead material”



# Belle II

## SuperKEKB:

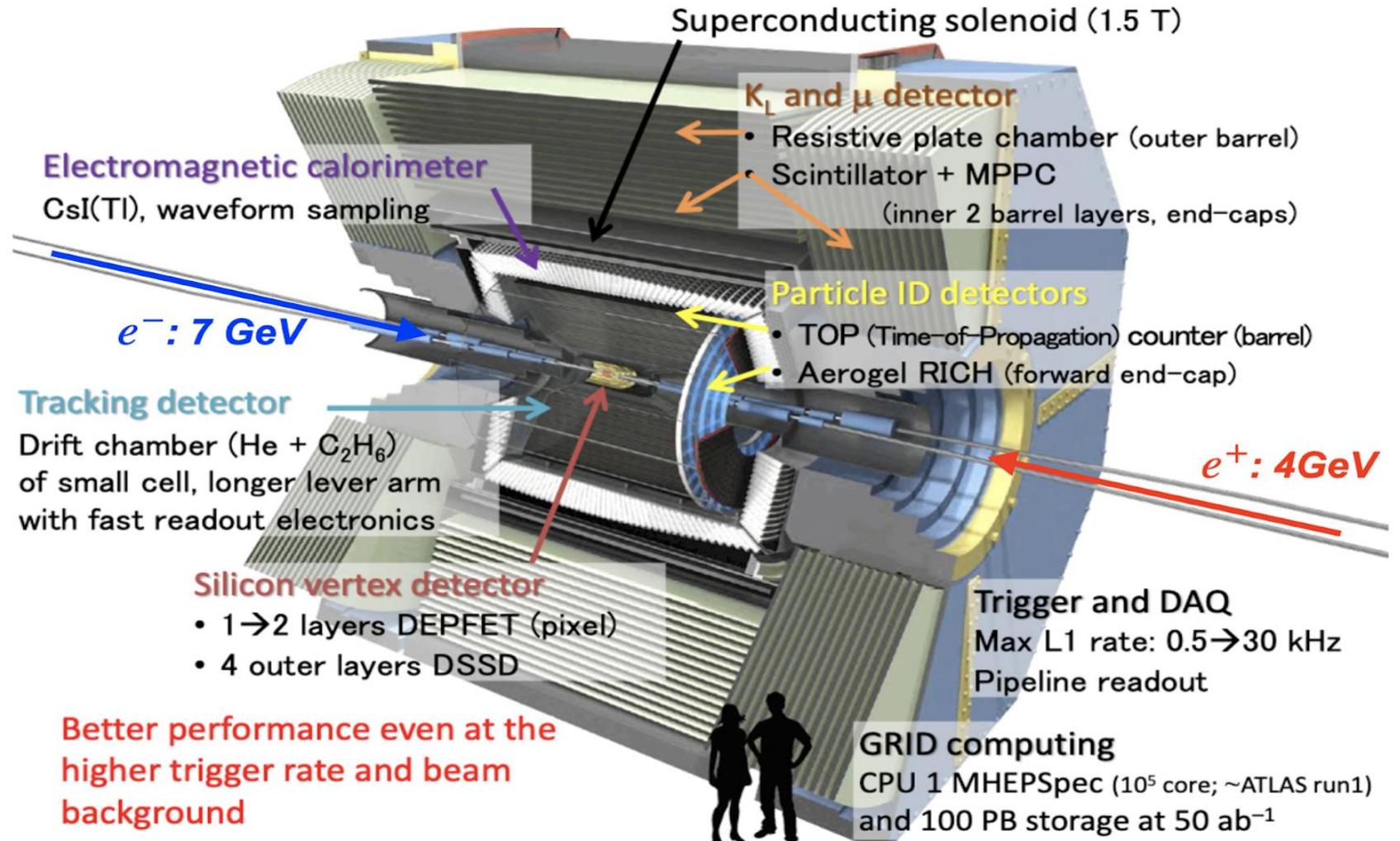
- Asymmetric **e+(4GeV) e- (7GeV)** collider in Tsukuba, Japan
- Operating around the **Y(4S)** resonance ( $\sqrt{s} = 10.58$  GeV)



# Belle II

**Includes gaseous tracking detector system: central drift chamber**

➤ **Ageing challenges!**

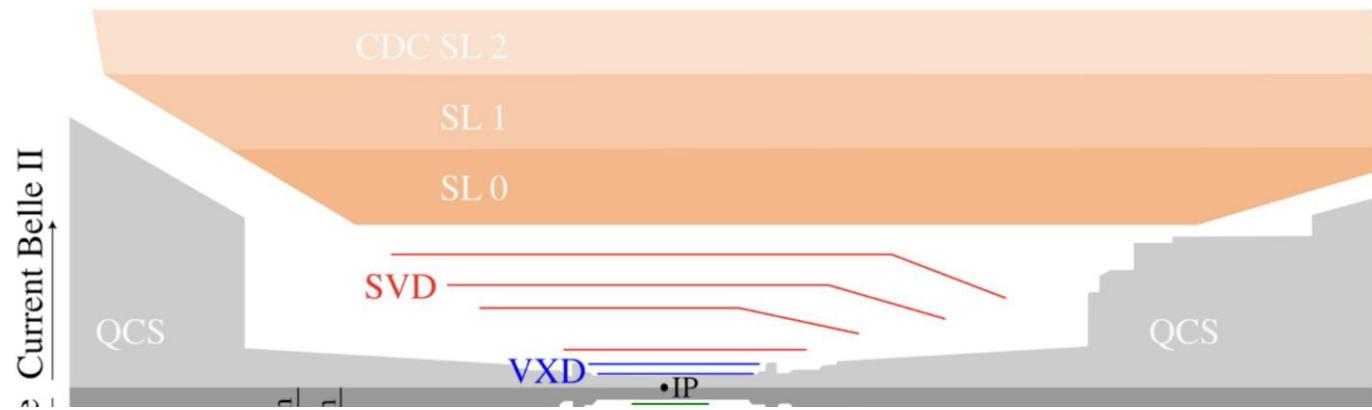


# Implementing a TOF layer?

Addition of an AC-LGAD –based TOF layer??

To consider:

- Radius of TOF layer?
- 1 layer with timing, or more? (>2 unlikely, due to material budget)
- Spatial resolution? Utilization in tracking as well?

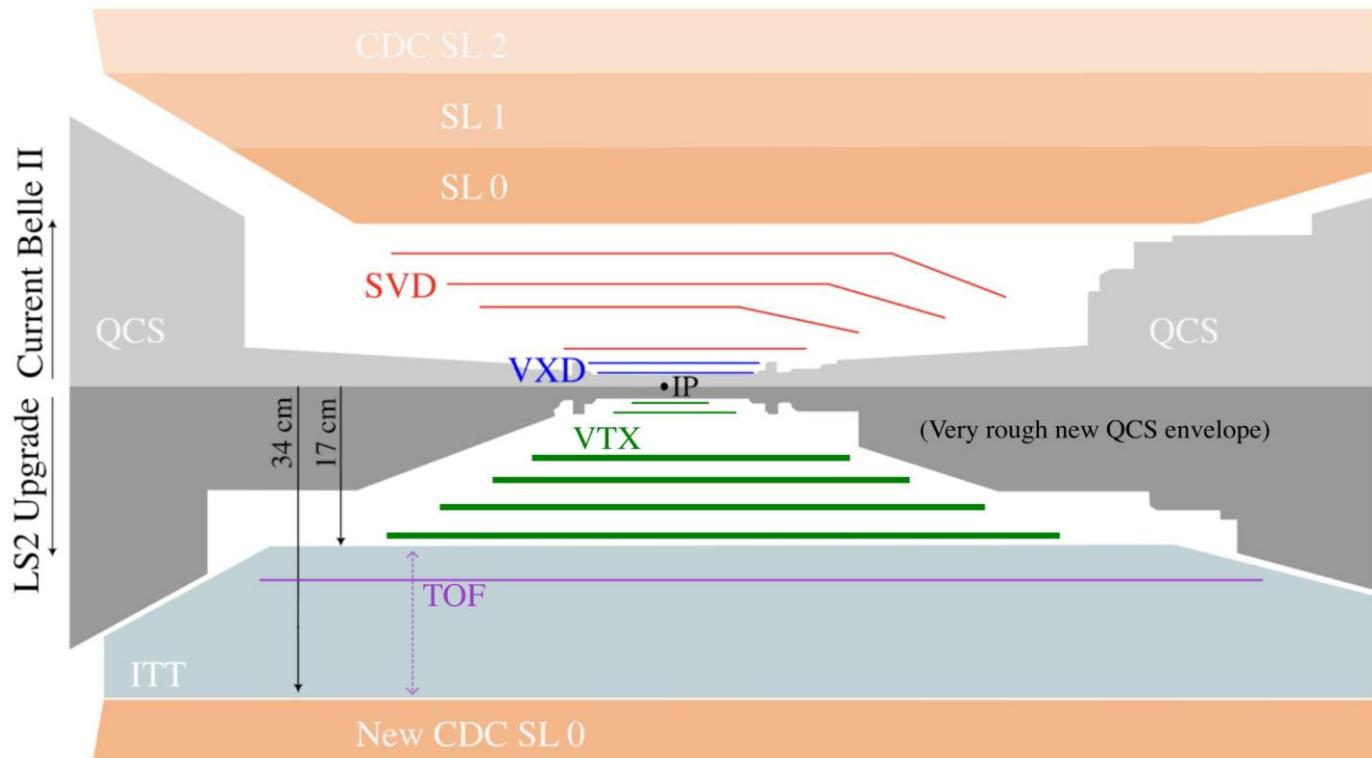


# Implementing a TOF layer?

Addition of an AC-LGAD –based TOF layer??

Target not only recovery of CDC particle ID capabilities, but aim to generate additional value:

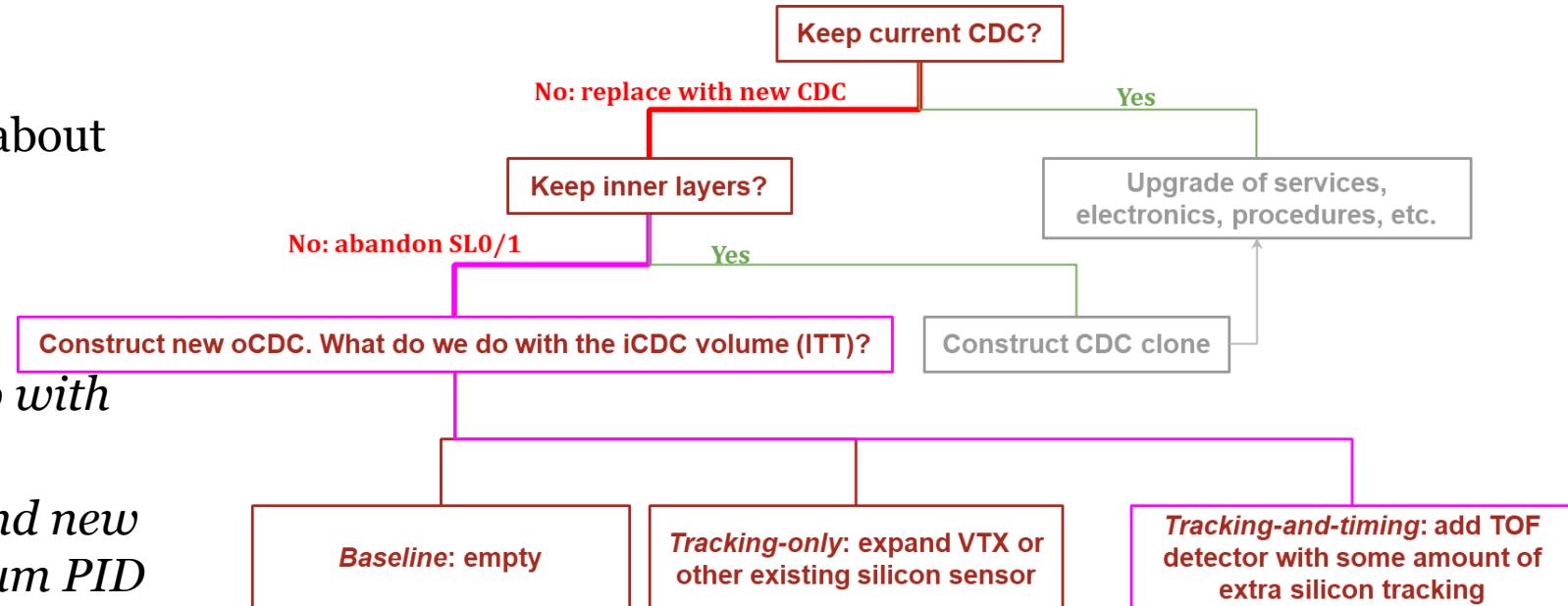
- *TOF would give low- $p_T$  PID capabilities totally new to  $B$ -factories*
- *Approximate doubling of efficiency for channels with low-momentum muons, for example leptonic tau decays ( $R(D^*)$ ,  $K \rightarrow \tau\tau$ , etc)*



# Belle II upgrade

## Upgrade of the Inner region:

- IR: New QCS - ongoing discussions about different upgrade options
- PXD + SVD → 5-layer VTX
  - CDC: gas aging issue → *what to do with this volume?*
  - *If left empty: Gap between VTX and new CDC layer degrades low-momentum PID*
- ***Can it be recovered by a fast timing layer through time-of-flight particle ID?***



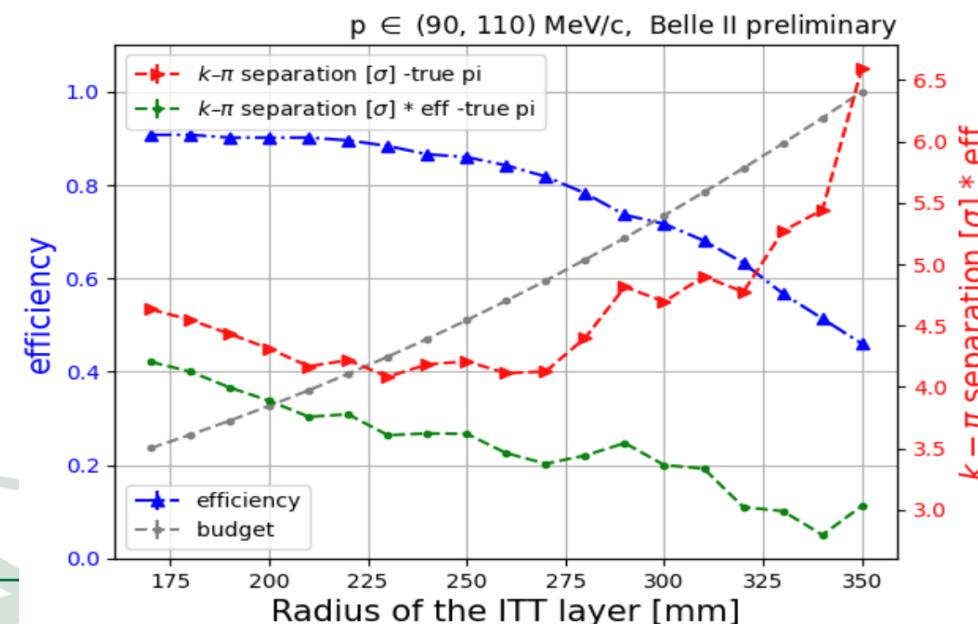
This is the 'working scenario' as of now

# Initial simulations and detector requirements

*Initial work: Geant4 simulations to quantify impact on PID, exercise placement at different radii, set constraints on  $X/X_0$*

- Simple cylindrical volume with some specified radius, thickness and timing resolution – sensor technology, mechanical design etc not defined

**Example:  $k - \pi$  separation**

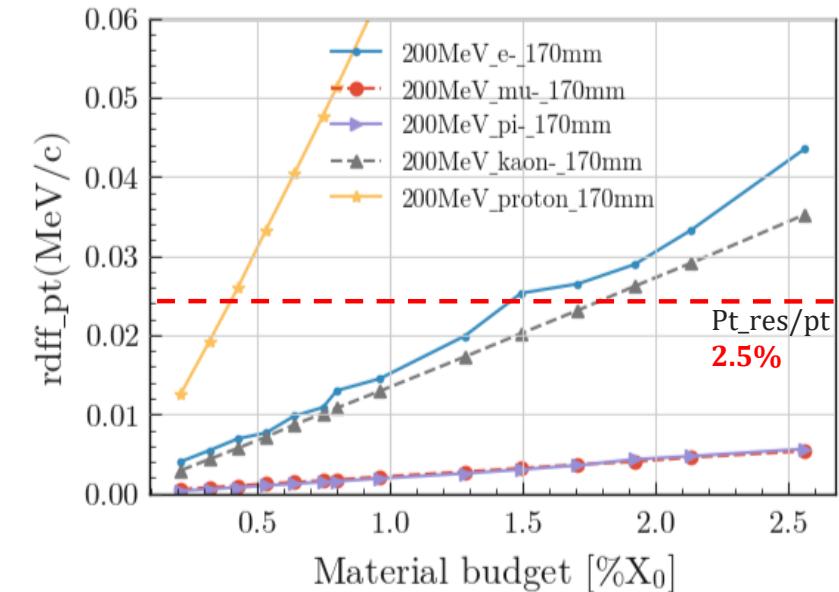
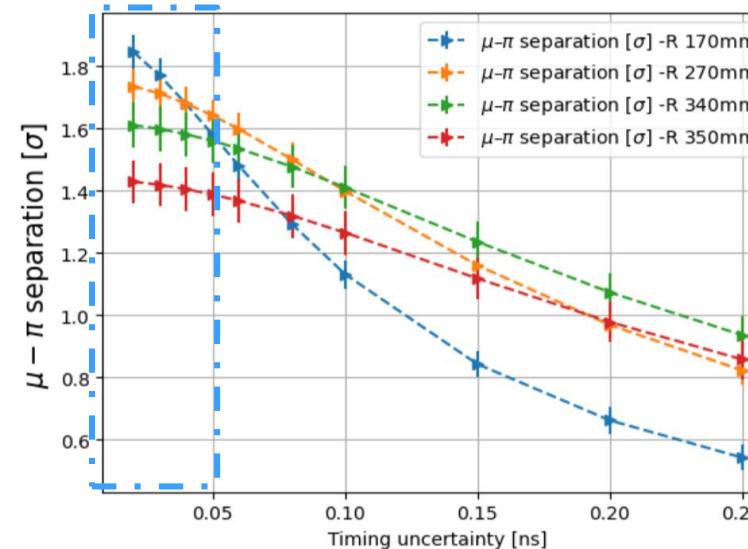
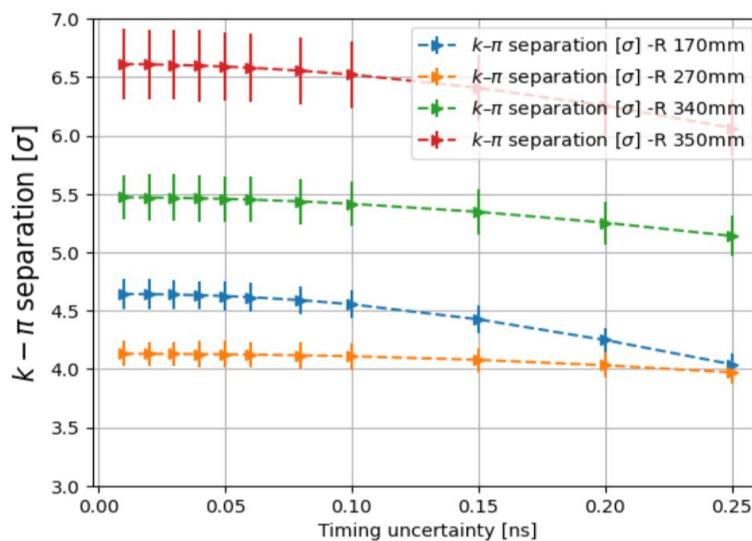


# Initial simulations and detector requirements

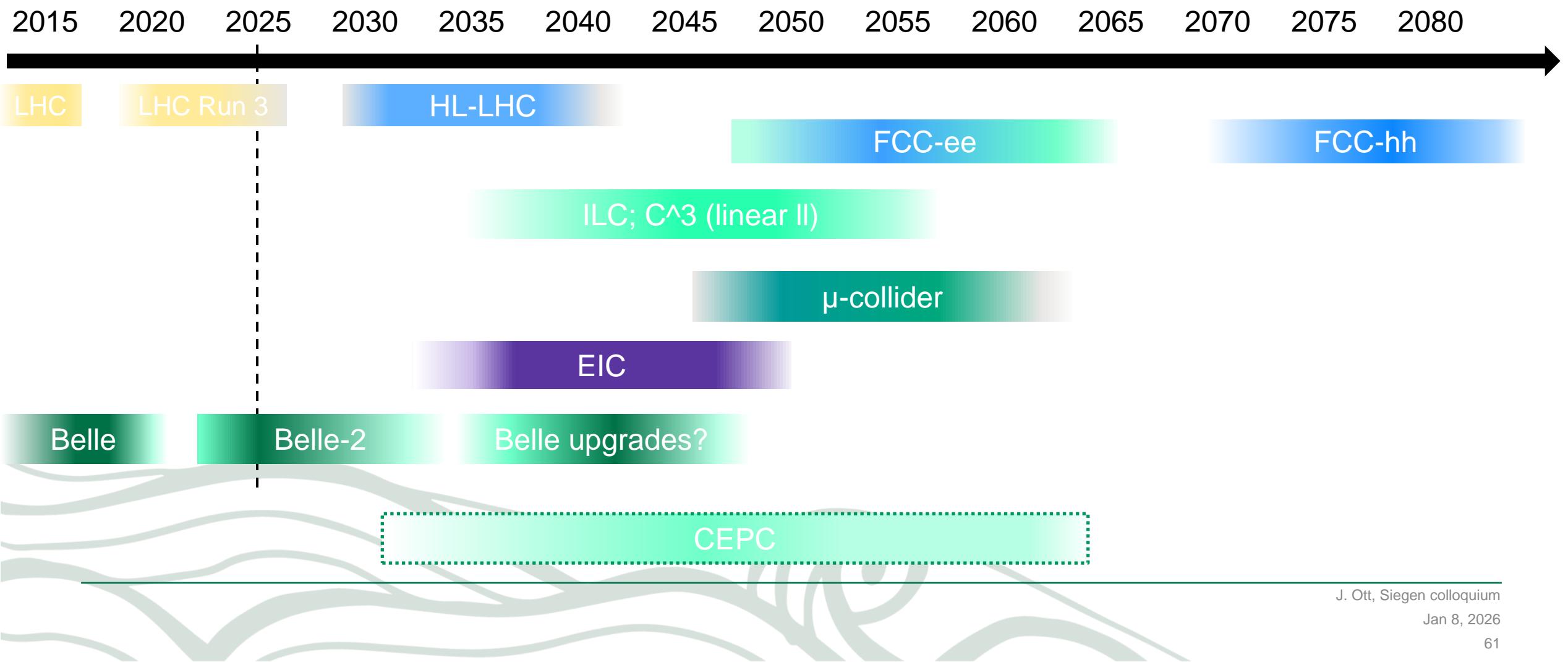
## $k - \pi$ (ref.) and $\mu - \pi$ (novel impact physics) separation

- Timing resolution: 50 ps
- Material budget, low  $p_T$  tracks 100-200 MeV/c: 1.5 %  $X/X_0$

*Impact on tracking resolution equivalent to current tracker – VTX material*



# Landscape of colliders



# Monolithic CMOS detectors

## Active CMOS / MAPS

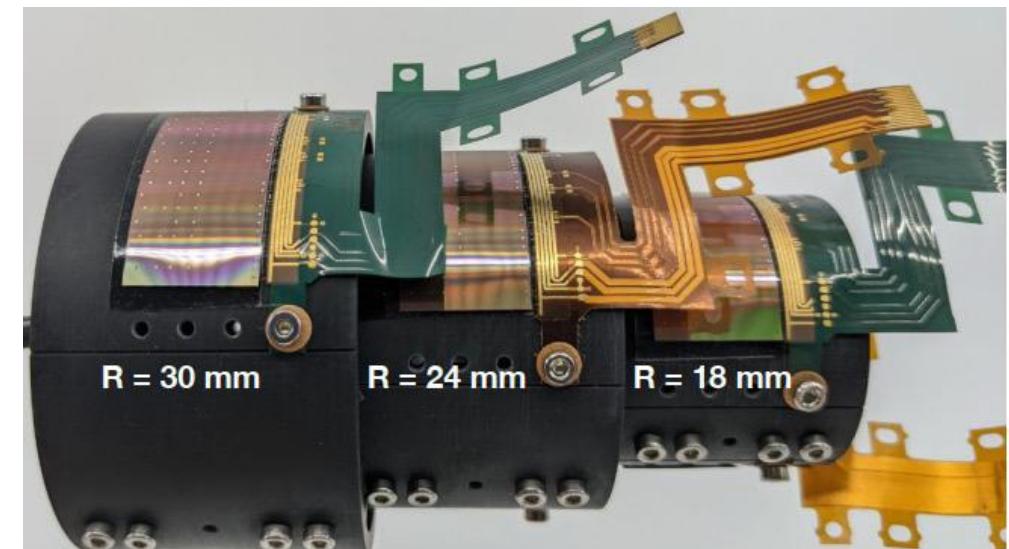
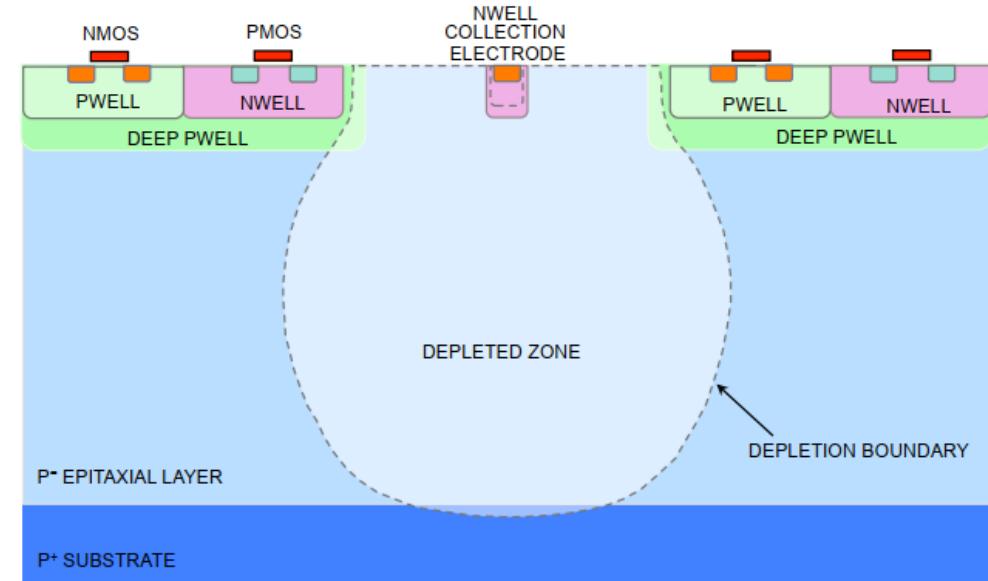
- Small pixels, better spatial resolution, do not require elaborate interconnection
- Commercial large vendor processes
- **Showstopper for p-p colliders so far: radiation levels**

## “Massless” detectors

Thin stitched detectors: ALICE ITS-3 for the HL-LHC upgrade

- **Baseline for inner tracker and vertex detector at most future colliders: EIC, FCC-ee, etc**

*Eventually MAPS with gain layer?*





***Thank you!***

***Mahalo!***

J. Ott, Siegen colloquium

Jan 8, 2026